

ADS931x Dual, Simultaneous-Sampling, Small-Size, 18-Bit, 5MSPS SAR ADC

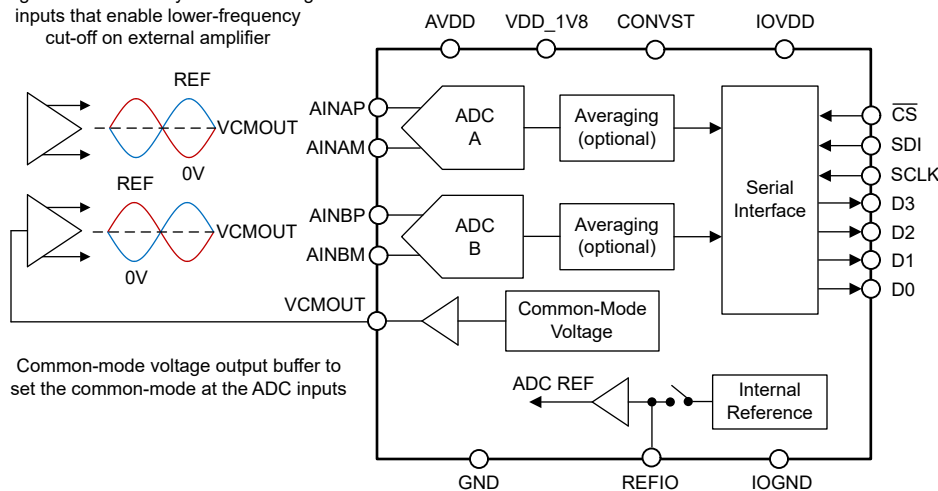
1 Features

- 18-bit SAR ADC family
 - ADS9317: 5MSPS/ch
 - ADS9316: 3MSPS/ch
- Two differential, simultaneously sampled channels
- Supports 5V and 3.3V analog supply operation
- Excellent DC and AC performance:
 - SNR: 95.4dB at 5MSPS
 - INL: $\pm 0.85\text{LSB}$, DNL: $\pm 0.4\text{LSB}$
- Feature integration:
 - Internal reference
 - Common-mode voltage output buffer
 - Integrated buffer for external reference input
 - Simple data average up to 128 samples
 - Moving data average up to 8 samples
- Configurable serial interface:
 - 2 serial outputs for each ADC channel
 - 1 serial output for each ADC channel
 - 1 serial output for both ADC channels
 - Supports daisy-chain functionality
- Extended temperature range: -40°C to $+125^{\circ}\text{C}$

2 Applications

- [Absolute optical encoders](#)
- [Servo drive position feedback](#)
- [Programmable DC power supplies, electronic loads](#)
- [SONAR](#)

Higher SNR with easy-to-drive analog inputs that enable lower-frequency cut-off on external amplifier



Device Block Diagram

3 Description

The ADS931x is a high-speed, dual, simultaneous-sampling, analog-to-digital converter (ADC) with an integrated reference and reference buffer. The ADS931x has excellent AC performance, which makes the device optimum for wide-bandwidth data acquisition (DAQ) systems.

The device supports an SPI-compatible serial interface. This interface makes the ADS931x easy to pair with a diversity of microcontrollers, digital signal processors (DSPs), and field-programmable gate arrays (FPGAs). This device also supports a data averaging feature that provides an AC performance boost in noisy environments.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾
ADS931x	VAE (VQFN, 22)	3.5mm × 3.5mm

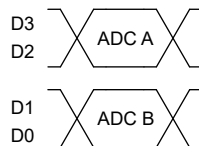
(1) For more information, see the [Mechanical, Packaging, and Orderable Information](#).

(2) The package size (length × width) is a nominal value and includes pins, where applicable.

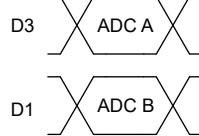
Device Information

PART NUMBER	RESOLUTION	SNR	INL
ADS931x	18 bits	95.4dB	$\pm 0.85\text{LSB}$

2 serial outputs per ADC



1 serial output per ADC



1 serial output for both ADCs

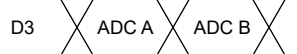


Table of Contents

1 Features	1	6.5 Programming.....	33
2 Applications	1	7 Register Map	40
3 Description	1	7.1 Register Bank 0.....	40
4 Pin Configuration and Functions	3	7.2 Register Bank 1.....	43
5 Specifications	5	8 Application and Implementation	59
5.1 Absolute Maximum Ratings.....	5	8.1 Application Information.....	59
5.2 ESD Ratings.....	5	8.2 Typical Application.....	59
5.3 Thermal Information.....	5	8.3 Power Supply Recommendations.....	61
5.4 Recommended Operating Conditions.....	6	8.4 Layout.....	61
5.5 Electrical Characteristics.....	7	9 Revision History	62
5.6 Electrical Characteristics: AVDD = 5V.....	8	10 Device and Documentation Support	63
5.7 Electrical Characteristics: AVDD = 3.3V.....	9	10.1 Documentation Support.....	63
5.8 Timing Requirements.....	10	10.2 Receiving Notification of Documentation Updates.....	63
5.9 Switching Characteristics.....	10	10.3 Support Resources.....	63
5.10 Timing Diagrams.....	11	10.4 Trademarks.....	63
5.11 Typical Characteristics.....	14	10.5 Electrostatic Discharge Caution.....	63
6 Detailed Description	22	10.6 Glossary.....	63
6.1 Overview.....	22	11 Mechanical, Packaging, and Orderable Information	63
6.2 Functional Block Diagram.....	22	11.1 Mechanical Data.....	64
6.3 Feature Description.....	22		
6.4 Device Functional Modes.....	32		

4 Pin Configuration and Functions

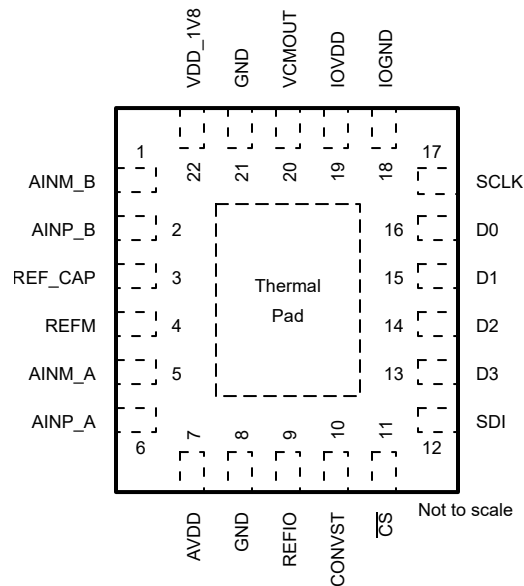


Figure 4-1. VAE Package, 22-Pin VQFN (Top View)

Table 4-1. Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
AINM_A	5	I	Negative analog input for ADC A.
AINM_B	1	I	Negative analog input for ADC B.
AINP_A	6	I	Positive analog input for ADC A.
AINP_B	2	I	Positive analog input for ADC B.
AVDD	7	P	5V or 3.3V analog power-supply pin. Connect a 1µF decoupling capacitor between pins 7 and 8.
CONVST	10	I	Conversion start input pin. A CONVST falling edge starts the conversion for ADC A and ADC B.
\overline{CS}	11	I	Chip-select input pin; active low. The host and device communicate when \overline{CS} is low. The data output pins go to Hi-Z when \overline{CS} is high.
D0	16	O	Serial communication pin: data output 0.
D1	15	O	Serial communication pin: data output 1.
D2	14	O	Serial communication pin: data output 2.
D3	13	O	Serial communication pin: data output 3.
GND	8, 21	G	Ground.
IOGND	18	G	Ground for IOVDD supply. Connect to GND externally.
IOVDD	19	P	Interface power-supply pin. Connect a 0.1µF decoupling capacitor between pins 18 and 19.
REFIO	9	I/O	Internal reference output. External reference input. Connect a 1µF decoupling capacitor to GND.
REF_CAP	3	O	Internal reference voltage output. Connect a 1µF decoupling capacitor between pins 3 and 4.
REFM	4	G	Negative reference input for the ADCs. Externally connect to the device GND.
SCLK	17	I	Clock input pin for the serial interface.

Table 4-1. Pin Functions (continued)

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
SDI	12	I	Serial data input pin. This pin programs the device registers.
VCMOUT	20	O	Common-mode voltage output. Use VCMOUT to set the common-mode voltage at the ADC inputs. Connect a 100nF decoupling capacitor to ground.
VDD_1V8	22	P	1.8V analog power-supply pin. Connect a 1µF decoupling capacitor between pins 21 and 22.
Thermal Pad	Pad	P	Exposed thermal pad. Connect to GND.

(1) I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power.

5 Specifications

5.1 Absolute Maximum Ratings

over operating ambient temperature range (unless otherwise noted)⁽¹⁾

	MIN	MAX	UNIT
AVDD to GND	-0.3	5.5	V
VDD_1V8 to GND	-0.3	2.1	V
IOVDD to IOGND	-0.3	3.7	V
AINP_A, AINM_A, AINP_B, and AINM_B to GND	-0.3	AVDD + 0.3	V
REFIO to REFM	-0.3	AVDD + 0.3	V
Digital inputs to IOGND	-0.3	IOVDD + 0.3	V
REFM to GND	-0.3	0.3	V
IOGND to GND	-0.3	0.3	V
Input current to any pin except supply pins ⁽²⁾	-10	10	mA
Junction temperature, T _J	-40	150	°C
Storage temperature, T _{stg}	-60	150	°C

- (1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) Limit pin current to 10 mA or less.

5.2 ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/ JEDEC JS-001, all pins ⁽¹⁾	±2000
		Charged device model (CDM), per ANSI/ESDA/ JEDEC JS-002, all pins ⁽²⁾	±500
			V

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

5.3 Thermal Information

THERMAL METRIC ⁽¹⁾		ADS931x	UNIT
		VAE (VQFN)	
		22 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	36.5	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	26.5	°C/W
R _{θJB}	Junction-to-board thermal resistance	7.9	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	0.8	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	7.8	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	11.8	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application note.

5.4 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER SUPPLY						
AVDD	Analog power supply	AVDD to GND, AVDD = 5V	4.5	5	5.5	V
		AVDD to GND, AVDD = 3.3V	3.1	3.3	3.5	
VDD_1V8	Power supply	VDD_1V8 to GND	1.75	1.8	1.85	V
IOVDD	Interface supply	IOVDD to IOGND	1.75		3.5	V
REFERENCE VOLTAGE						
V _{REF}	Reference voltage to the ADC	External reference, AVDD = 5V	2.48	4.096	4.116	V
		External reference, AVDD = 3.3V	2.48	2.5	2.52	
ANALOG INPUTS						
V _{IN}	Absolute input voltage	AINx ⁽¹⁾ to GND	0		AVDD	V
FSR	Full-scale input range	(AINP_x – AINM_x)	–V _{REF}		V _{REF}	V
V _{CM}	Common-mode input range	(AINP_x + AINM_x) / 2	V _{CMOUT} – 0.04		V _{CMOUT} + 0.04	V
TEMPERATURE RANGE						
T _A	Ambient temperature		–40	25	125	°C

(1) AINx refers to analog inputs AINP_A, AINP_B, AINM_A, and AINM_B.

5.5 Electrical Characteristics

at AVDD = 3V to 5.5V, VDD_1V8 = 1.75V to 1.85V, internal reference, and maximum throughput (unless otherwise noted); minimum and maximum values at T_A = –40°C to +125°C; typical values at T_A = 25°C

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
DC PERFORMANCE						
	Resolution	No missing codes		18		Bits
DNL	Differential nonlinearity		–0.65	±0.4	0.65	LSB
INL	Integral nonlinearity		–2	±0.85	2	LSB
V _(OS)	Input offset error		–3.5	±0.7	3.5	LSB
dV _{OS} /dT	Input offset error thermal drift			0.6	1.6	µV/°C
	Offset error match	V _(OS) (ADC_A – ADC_B)		±1		LSB
G _E	Gain error ⁽¹⁾		–0.02	±0.002	0.02	%FSR
dG _E /dT	Gain error thermal drift	Reference buffer on ⁽¹⁾		0.8	1.8	ppm/°C
dG _E /dT	Gain error thermal drift	Reference buffer off ⁽²⁾		0.2	0.6	ppm/°C
	Gain error match	G _E (ADC_A – ADC_B)		±0.002		%FSR
CMRR	Common-mode rejection ratio	f _{IN} = dc to 1kHz, V _{INCM} = 50mV _{PP}		70		dB
POWER SUPPLY						
PSRR	Power-supply rejection ratio	100mV _{pp} ripple on AVDD or VDD_1V8 of frequency < 100kHz		80		dB
ANALOG INPUTS						
CSH	Sampling capacitance			18		pF
BW	Analog input bandwidth (large signal)	–0.1dB input signal		1.5		MHz
I _B	Analog input leakage current	Idle-channel		0.5	1	µA
COMMON-MODE OUTPUT BUFFER						
V _{CMOUT}	Common-mode output voltage	V _{REF} = 4.096V, VCMOUT_SEL = 0b	2.21	2.23	2.25	V
	Output current drive		0		15	µA
INTERNAL REFERENCE						
V _{REF}	Voltage on REFIO pin (configured as output)	1µF capacitor on REFIO pin, T _A = 25°C	V _{REF} – 0.005	V _{REF}	V _{REF} + 0.005	V
	Reference temperature drift			5	15	ppm/°C
DIGITAL INPUTS						
V _{IL}	Input low logic level				0.3 IOVDD	V
V _{IH}	Input high logic level		0.7 IOVDD			V
DIGITAL OUTPUTS						
V _{OL}	Output low logic level	I _{OL} = 200µA sink	0		0.4	V
V _{OH}	Output high logic level	I _{OH} = 200µA source	IOVDD – 0.4		IOVDD	V
SAMPLING DYNAMICS						
t _A	Aperture delay			4		ns
	Aperture mismatch			100		ps
t _{JITTER}	Aperture jitter			1		ps

(1) These specifications include full temperature range variation but not the error contribution from internal reference.

(2) For more details, see [External Reference with External Reference Buffer](#).

5.6 Electrical Characteristics: AVDD = 5V

at AVDD = 4.5V to 5.5V, VDD_1V8 = 1.75V to 1.85V, IOVDD = 1.75V to 3.3V, internal V_{REF} = 4.096V, and maximum throughput (unless otherwise noted); minimum and maximum values at T_A = –40°C to +125°C; typical values at T_A = 25°C

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
AC PERFORMANCE						
SINAD	Signal-to-noise + distortion ratio	f _{IN} = 2kHz (ADS9317)	92.9	95.3		dB
		f _{IN} = 2kHz (ADS9316)	93.1	95.7		
		f _{IN} = 1MHz		92.8		
SNR	Signal-to-noise ratio	f _{IN} = 2kHz (ADS9317)	92.9	95.4		dB
		f _{IN} = 2kHz (ADS9316)	93.1	95.8		
		f _{IN} = 1MHz		92.9		
THD	Total harmonic distortion	f _{IN} = 2kHz		–115		dB
		f _{IN} = 1MHz		–100		
SFDR	Spurious-free dynamic range	f _{IN} = 2kHz		115		dB
		f _{IN} = 1MHz		100		
	Channel-to-channel isolation	V _{IN_ADCA} = 0V, f _{IN_ADCB} = 10kHz at 100% FSR		–110		dB
POWER SUPPLY						
I _{AVDD}	Supply current from AVDD	Full-speed (ADS9317)		4.3	4.7	mA
		Full-speed (ADS9316)		2.7	3.1	
		No conversion (idle) (ADS9317)		1.5	1.8	
		No conversion (idle) (ADS9316)		1.05	1.3	
		Power-down		0.35	0.7	
I _{VDD_1V8}	Supply current from VDD_1V8	Full-speed (ADS9317)		9.8	10.4	mA
		Full-speed (ADS9316)		7.2	7.7	
		No conversion (idle) (ADS9317)		6.8	7.3	
		No conversion (idle) (ADS9316)		5.2	5.7	
		Power-down		0.8	1	
I _{IOVDD}	Supply current from IOVDD	Full-speed (ADS9317), C _{LOAD} = 10pF		2.7	3	mA
		Full-speed (ADS9316), C _{LOAD} = 10pF		1.6	1.8	
		No conversion (idle), C _{LOAD} = 10pF		0.25	0.35	
		Power-down, C _{LOAD} = 10pF		0.25	0.35	

5.7 Electrical Characteristics: AVDD = 3.3V

at AVDD = 3.1V to 3.5V, VDD_1V8 = 1.75V to 1.85V, IOVDD = 1.75V to 3.3V, internal V_{REF} = 2.5V, and maximum throughput (unless otherwise noted); minimum and maximum values at T_A = –40°C to +125°C; typical values at T_A = 25°C

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
AC PERFORMANCE						
SINAD	Signal-to-noise + distortion ratio	f _{IN} = 2kHz (ADS9317)	89.4	91.4		dB
		f _{IN} = 2kHz (ADS9316)	89.6	91.6		
		f _{IN} = 1MHz		88.8		
SNR	Signal-to-noise ratio	f _{IN} = 2kHz (ADS9317)	89.5	91.5		dB
		f _{IN} = 2kHz (ADS9316)	89.7	91.7		
		f _{IN} = 1MHz		88.9		
THD	Total harmonic distortion	f _{IN} = 2kHz		–112		dB
		f _{IN} = 1MHz		–100		
SFDR	Spurious-free dynamic range	f _{IN} = 2kHz		112		dB
		f _{IN} = 1MHz		100		
	Channel-to-channel isolation	V _{IN_ADCA} = 0V, f _{IN_ADCB} = 10kHz at 100% FSR		–110		dB
POWER SUPPLY						
I _{AVDD}	Supply current from AVDD	Full-speed (ADS9317)		3	3.4	mA
		Full-speed (ADS9316)		1.9	2.3	
		No conversion (idle) (ADS9317)		1.4	1.65	
		No conversion (idle) (ADS9316)		0.94	1.2	
		Power-down		0.35	0.7	
I _{VDD_1V8}	Supply current from VDD_1V8	Full-speed (ADS9317)		9.8	10.4	mA
		Full-speed (ADS9316)		7.2	7.7	
		No conversion (idle) (ADS9317)		6.8	7.3	
		No conversion (idle) (ADS9316)		5.2	5.7	
		Power-down		0.8	1	
I _{IOVDD}	Supply current from IOVDD	Full-speed (ADS9317), C _{LOAD} = 10pF		2.7	3	mA
		Full-speed (ADS9316), C _{LOAD} = 10pF		1.6	1.8	
		No conversion (idle), C _{LOAD} = 10pF		0.25	0.35	
		Power-down, C _{LOAD} = 10pF		0.25	0.35	

5.8 Timing Requirements

at AVDD = 3V to 5.5V, VDD_1V8 = 1.75V to 1.85V, IOVDD = 1.75V to 3.3V, internal reference, and maximum throughput (unless otherwise noted); C_L = 10pF; minimum and maximum values at T_A = –40°C to +125°C; typical values at T_A = 25°C

			MIN	MAX	UNIT
CONVERSION CYCLE					
f _{CYCLE}	Sampling frequency	ADS9317		5	MHz
		ADS9316		3	
t _{CYCLE}	ADC cycle-time period		1/f _{CYCLE}		s
f _{CLK}	Maximum SCLK frequency			80	MHz
t _{CLK}	Minimum SCLK time period		12.5		ns
t _{ACQ}	Acquisition time	ADS9317	70		ns
		ADS9316	133.33		
t _{PH_CV}	CONVST high time		10		ns
t _{PL_CV}	CONVST low time		10		ns
SPI INTERFACE TIMINGS					
t _{hi_CSZ}	Pulse duration: \overline{CS} high		5		ns
t _{PH_CK}	SCLK high time		0.40	0.60	t _{CLK}
t _{PL_CK}	SCLK low time		0.40	0.60	t _{CLK}
t _{d_CSCK}	Setup time: \overline{CS} falling to the first SCLK rising edge		10		ns
t _{su_CKDI}	Setup time: SDI data valid to the corresponding SCLK rising edge		3		ns
t _{ht_CKDI}	Hold time: SCLK rising edge to corresponding data valid on SDI		1		ns
t _{ht_CVCS} ⁽¹⁾	Hold time: CONVST falling edge to \overline{CS} falling edge		0		ns
t _{ht_CKCS}	Hold time: last SCLK falling edge to \overline{CS} rising		10		ns
t _{LOW_LAT} ⁽²⁾	Hold time: time after t _{CONV} to \overline{CS} falling edge in low latency mode		30		ns

(1) Internally there is a 5ns delay enabled by default between CONVST falling edge and \overline{CS} falling edge.

(2) For more details, see the LL_DELAY register field description in register bank 1.

5.9 Switching Characteristics

at AVDD = 3V to 5.5V, VDD_1V8 = 1.75V to 1.85V, IOVDD = 1.75V to 3.3V, internal reference, and maximum throughput (unless otherwise noted); C_L = 10pF; minimum and maximum values at T_A = –40°C to +125°C; typical values at T_A = 25°C

PARAMETER		TEST CONDITIONS	MIN	MAX	UNIT
CONVERSION CYCLE					
t _{CONV}	ADC conversion time	ADS9317		130	ns
		ADS9316		200	
RESET					
t _{PU}	Power-up time for device			130	ms
SPI INTERFACE TIMINGS					
t _{den_CSDO}	Time delay: \overline{CS} falling edge to data valid on SDO			16	ns
t _{dz_CSDO}	Time delay: \overline{CS} rising edge to SDO going Hi-Z			7.5	ns
t _{ht_CKDO}	Hold time: SCLK launch edge to previous data valid on SDO		7.6		ns
t _{d_CKDO}	Time delay: SCLK launch edge to corresponding data valid on SDO			17	ns
t _{ECHO}	Time delay: SCLK launch edge to SCLK echo output on D0 in SCLK Echo mode			t _{d_CKDO} – 2	ns

5.10 Timing Diagrams

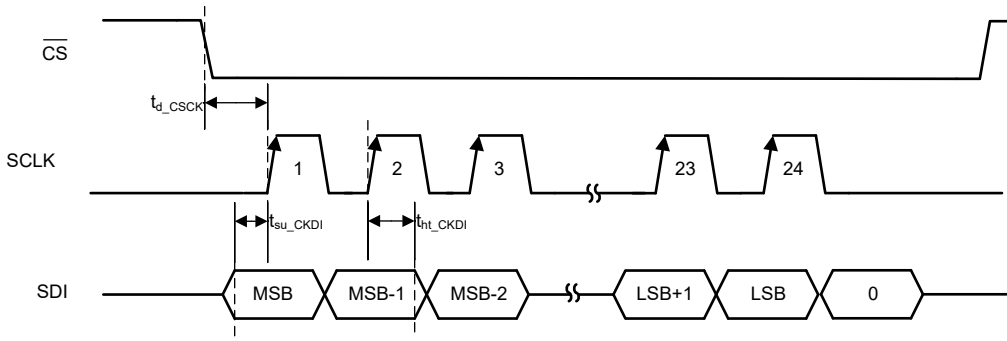


Figure 5-1. SDI Timing for Register Operations

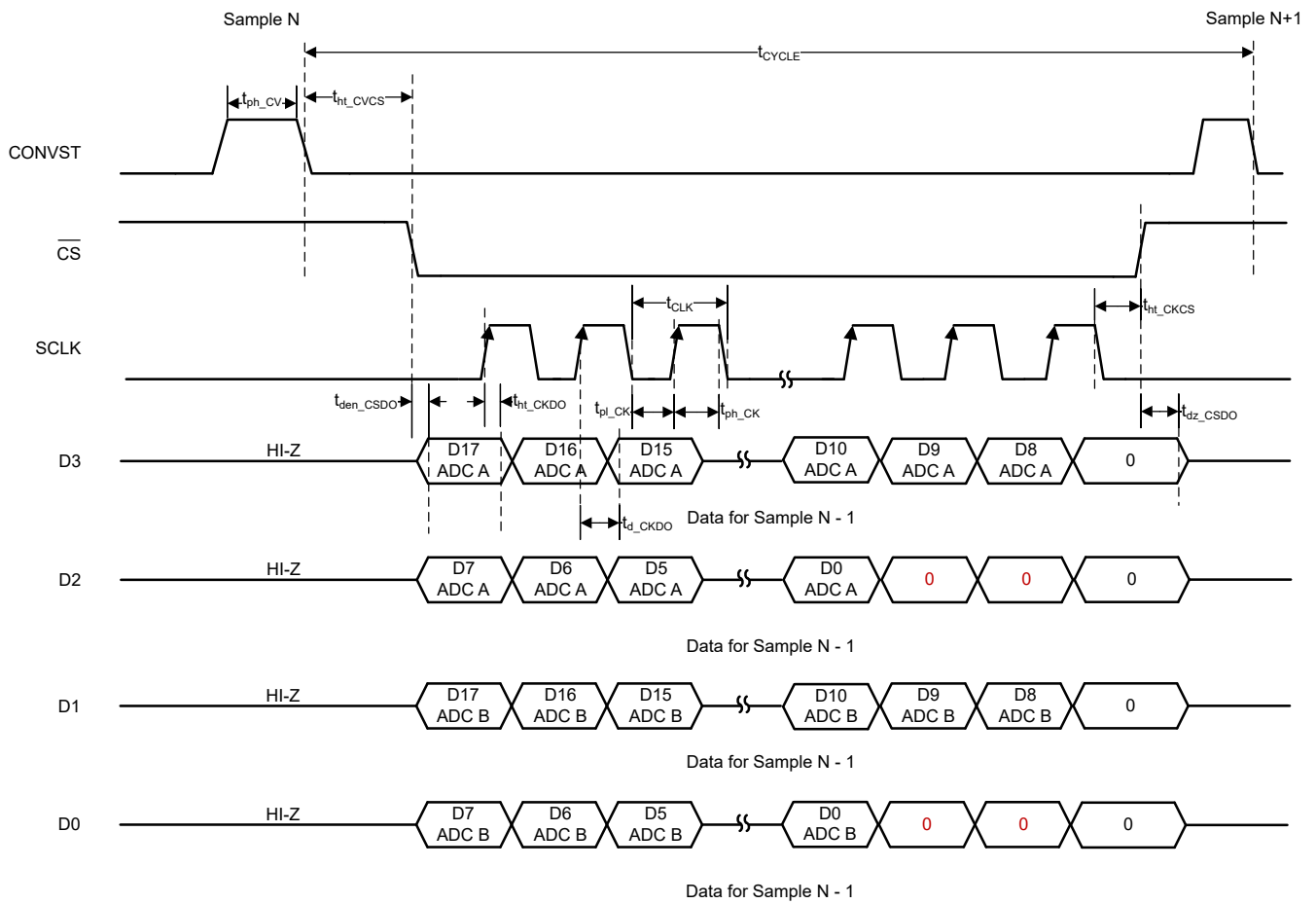


Figure 5-2. Conversion Cycle Timing: 4-Lane Default Operation

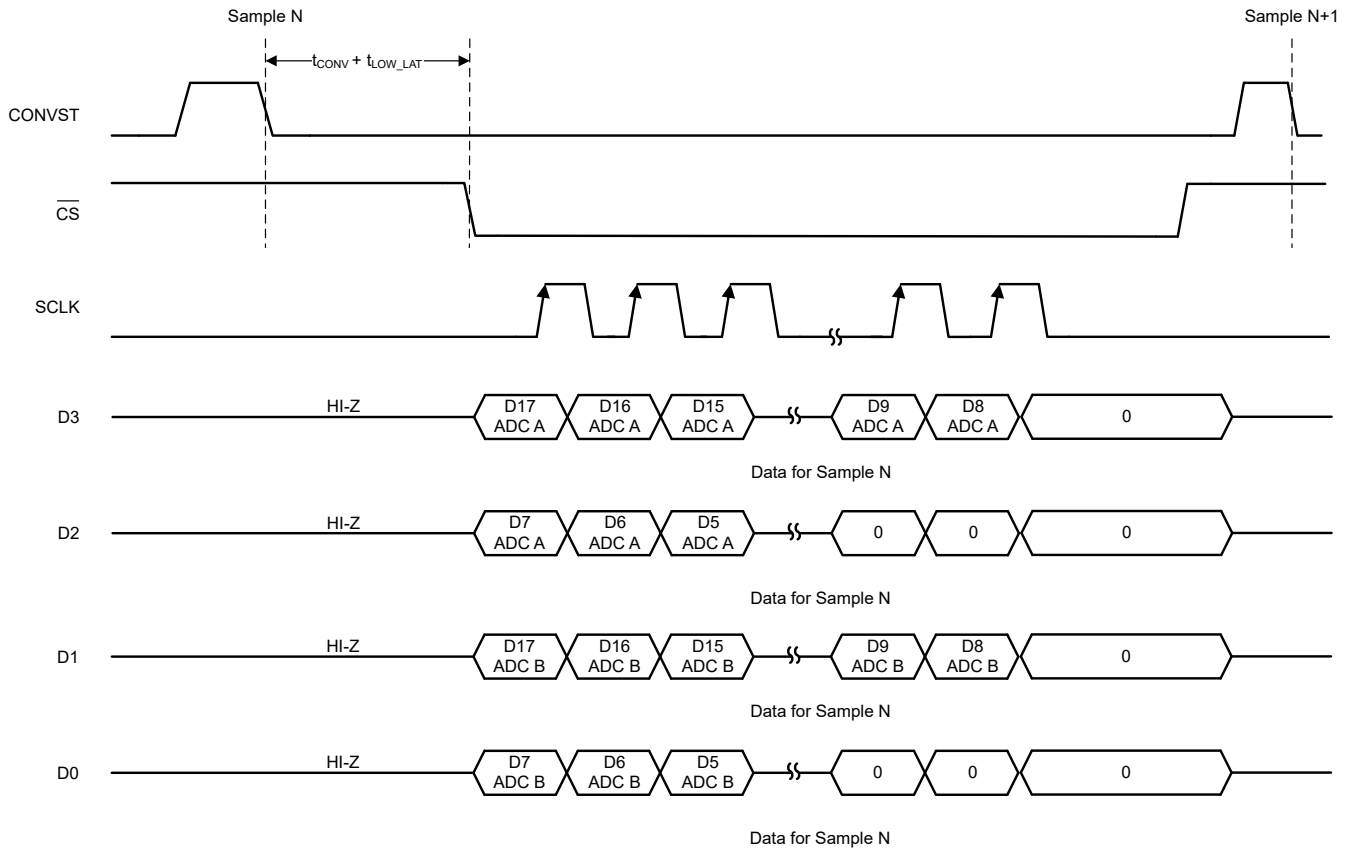


Figure 5-3. Conversion Cycle Timing: 4-Lane Low-Latency Mode

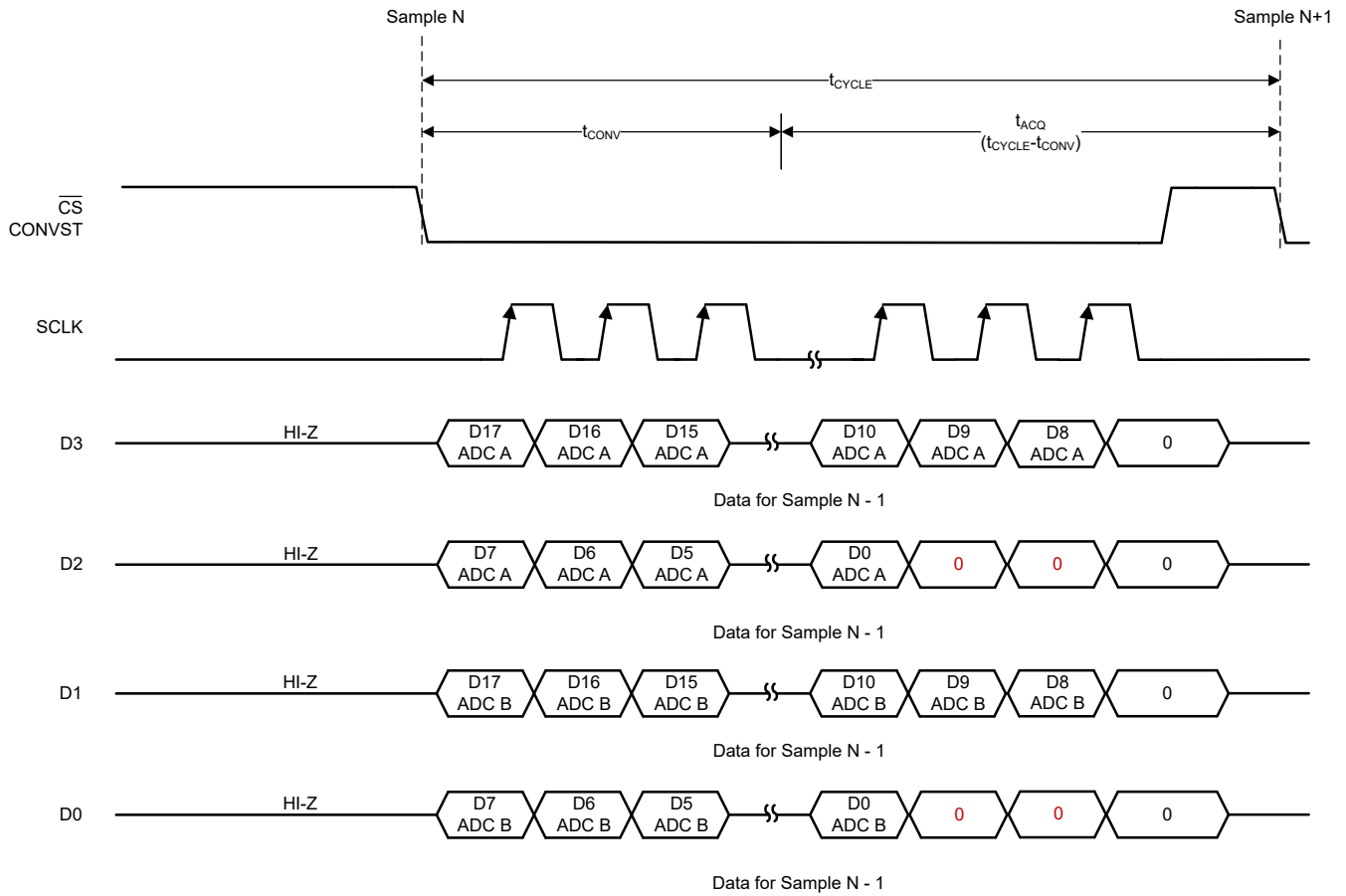


Figure 5-4. Conversion Cycle Timing: 4-Lane Mode with \overline{CS} and CONVST Shorted

5.11 Typical Characteristics

at $T_A = 25^\circ\text{C}$, $AVDD = 5\text{V}$, $VDD_{1V8} = 1.8\text{V}$, external $V_{REF} = 4.096\text{V}$, and maximum throughput (unless otherwise noted)

Each curve corresponds to a ADS931x unit under test.

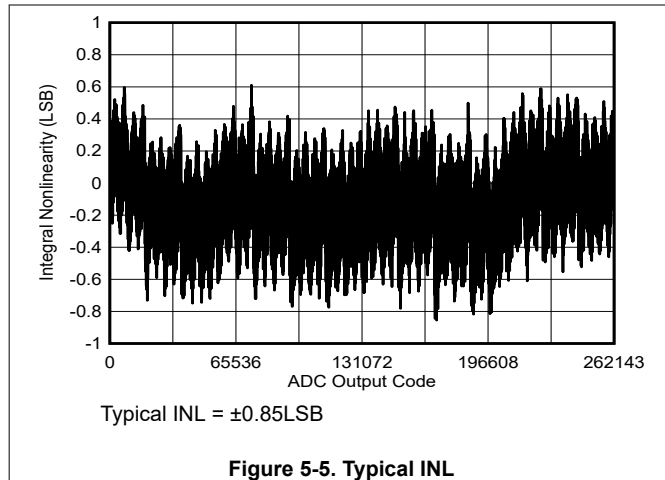


Figure 5-5. Typical INL

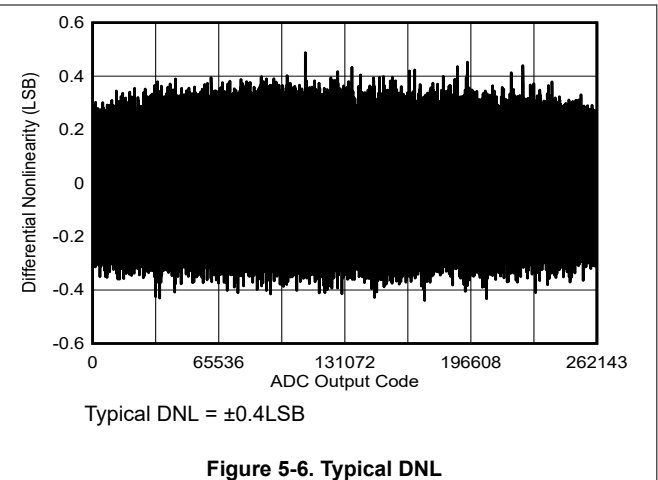


Figure 5-6. Typical DNL

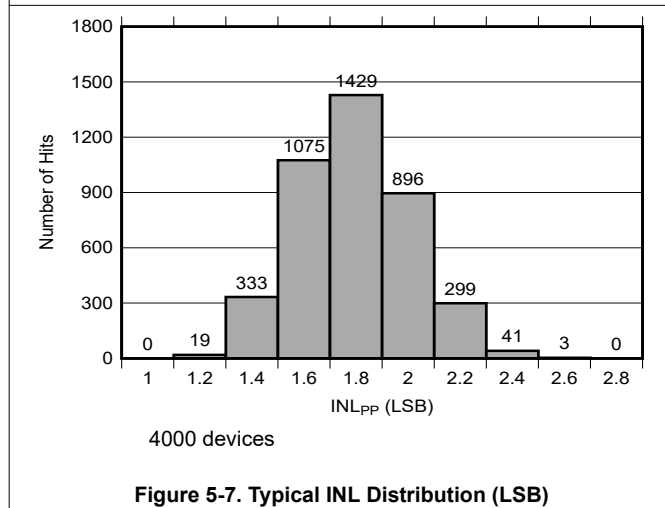


Figure 5-7. Typical INL Distribution (LSB)

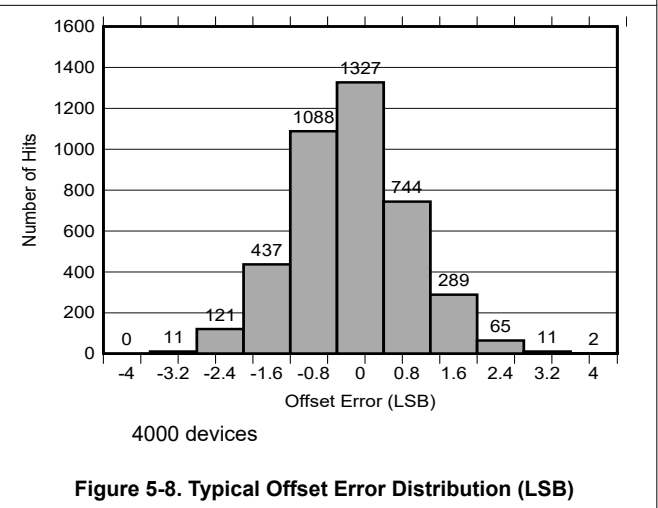


Figure 5-8. Typical Offset Error Distribution (LSB)

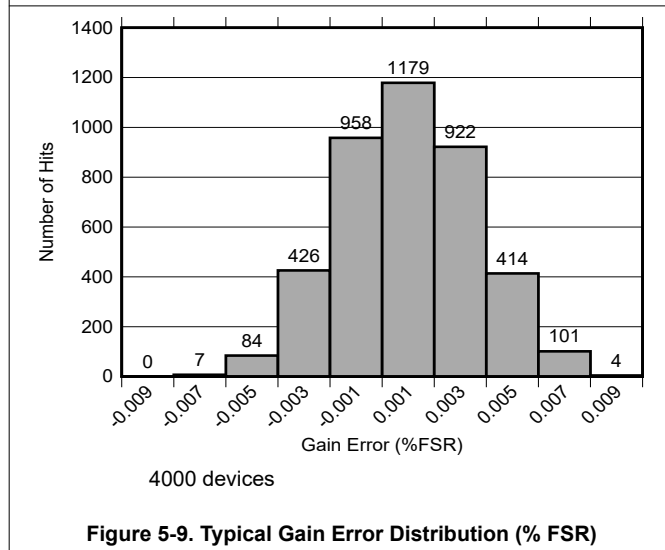


Figure 5-9. Typical Gain Error Distribution (%FSR)

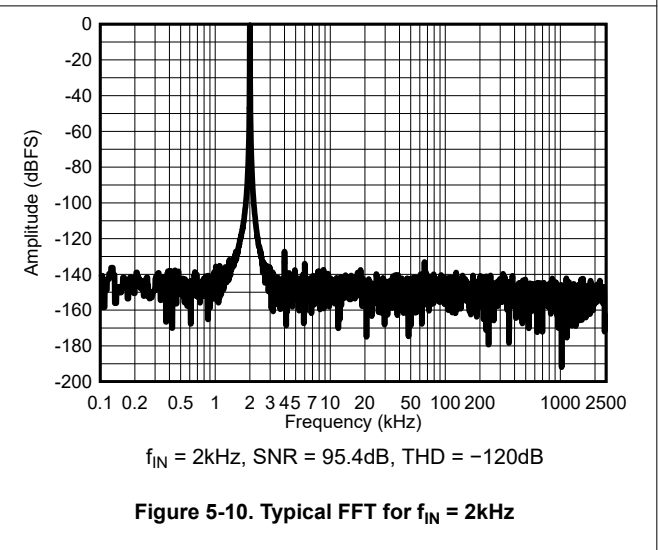


Figure 5-10. Typical FFT for $f_{IN} = 2\text{kHz}$

5.11 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $AVDD = 5\text{V}$, $VDD_1\text{V8} = 1.8\text{V}$, external $V_{REF} = 4.096\text{V}$, and maximum throughput (unless otherwise noted)

Each curve corresponds to a ADS931x unit under test.

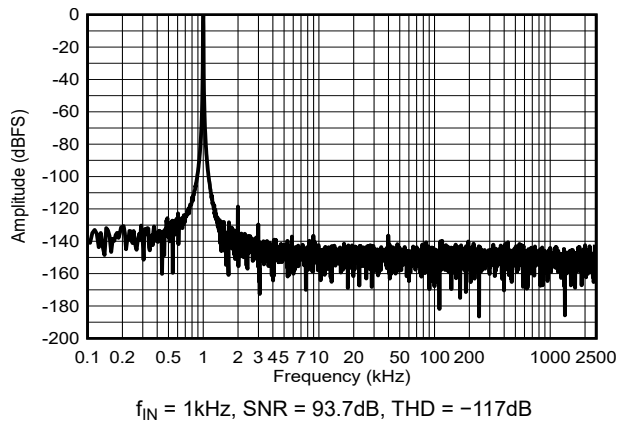


Figure 5-11. Typical FFT for $f_{IN} = 1\text{kHz}$, external $V_{REF} = 3.3\text{V}$

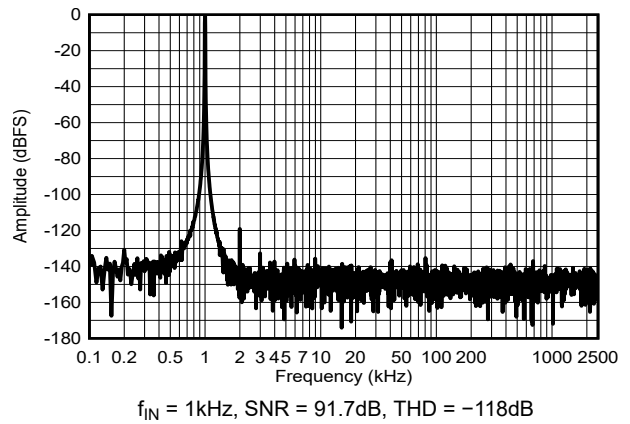


Figure 5-12. Typical FFT for $f_{IN} = 1\text{kHz}$, external $V_{REF} = 2.5\text{V}$

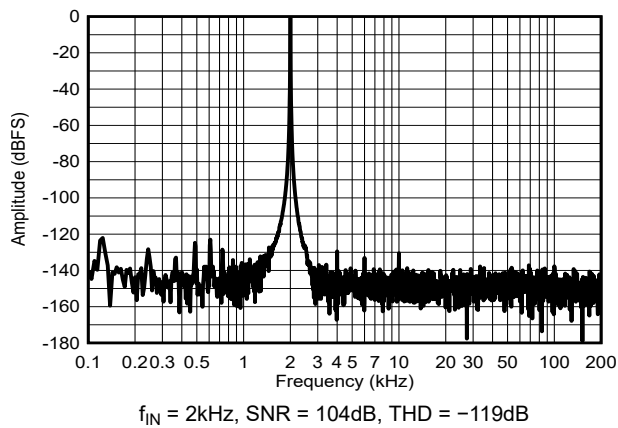


Figure 5-13. Typical FFT for $f_{IN} = 2\text{kHz}$, Simple Average With $OSR = 8$

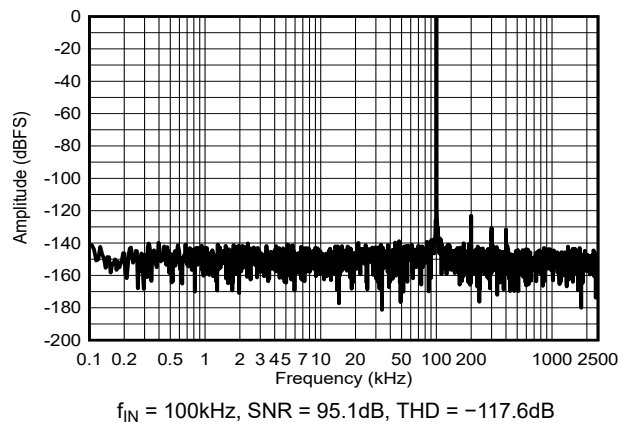


Figure 5-14. Typical FFT for $f_{IN} = 100\text{kHz}$

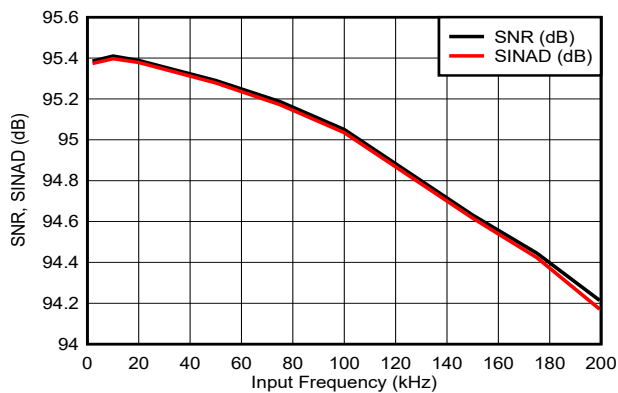


Figure 5-15. SNR and SINAD vs Input Signal Frequency

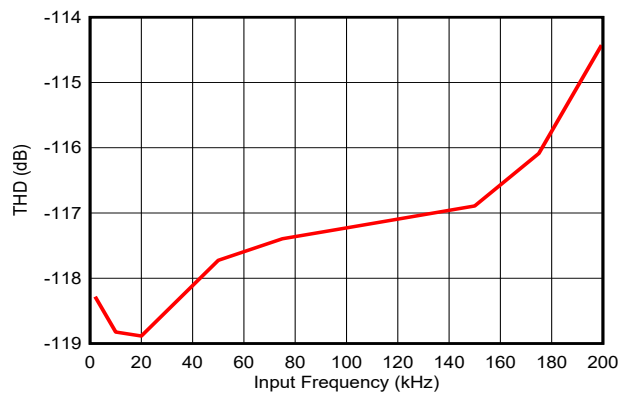
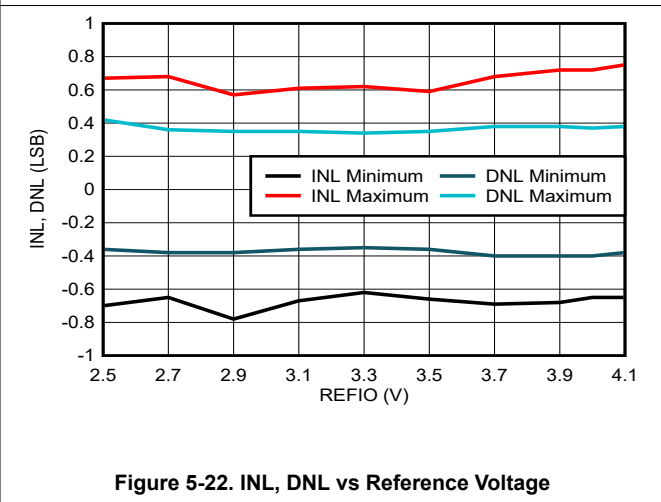
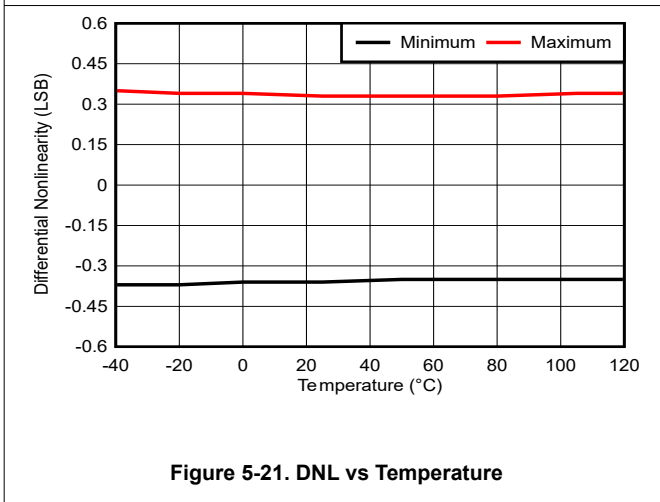
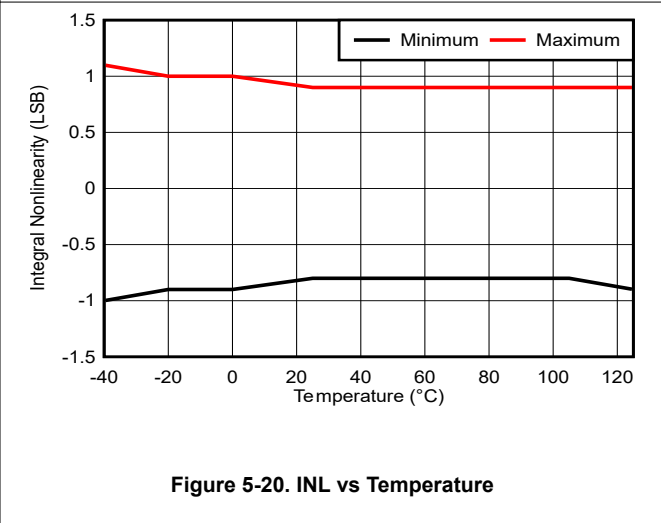
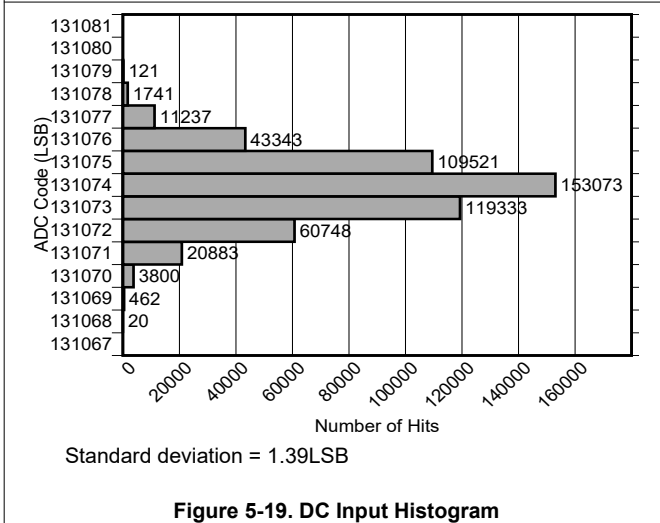
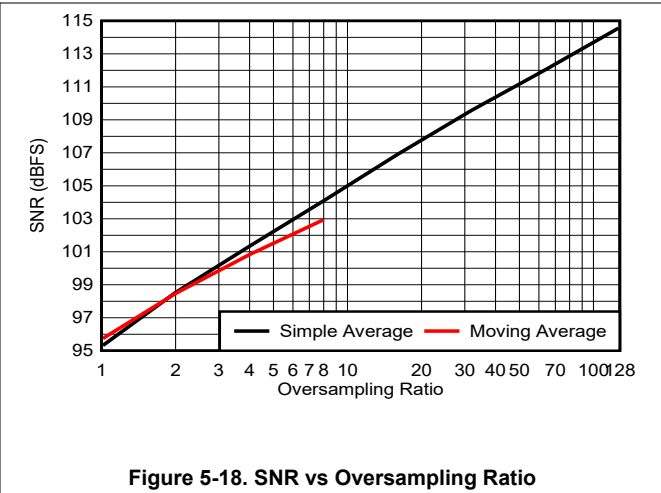
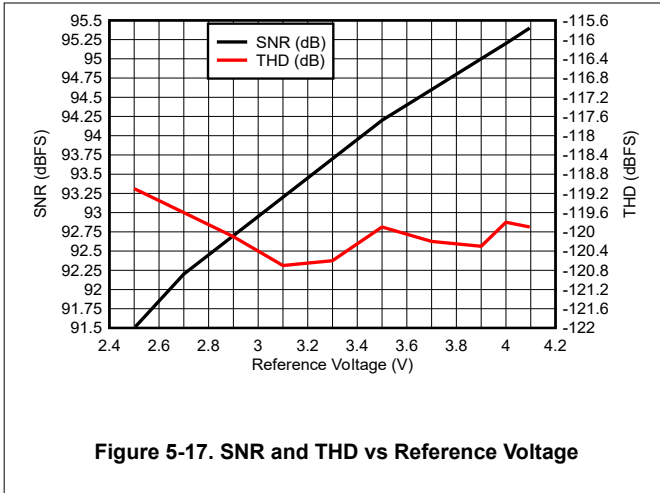


Figure 5-16. THD vs Input Signal Frequency

5.11 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $AVDD = 5\text{V}$, $VDD_{1V8} = 1.8\text{V}$, external $V_{REF} = 4.096\text{V}$, and maximum throughput (unless otherwise noted)

Each curve corresponds to a ADS931x unit under test.



5.11 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $AVDD = 5\text{V}$, $VDD_{1V8} = 1.8\text{V}$, external $V_{REF} = 4.096\text{V}$, and maximum throughput (unless otherwise noted)

Each curve corresponds to a ADS931x unit under test.

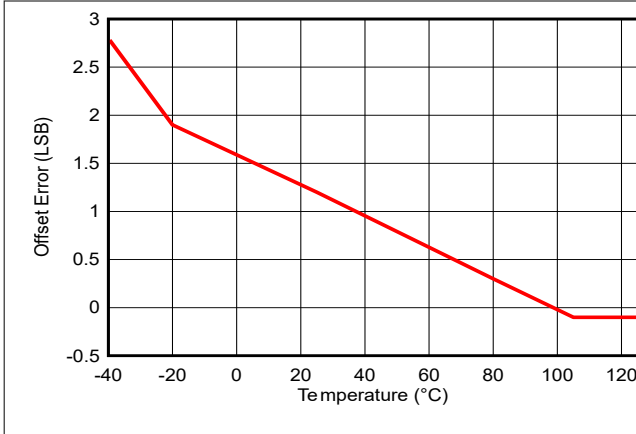


Figure 5-23. Offset Error vs Temperature

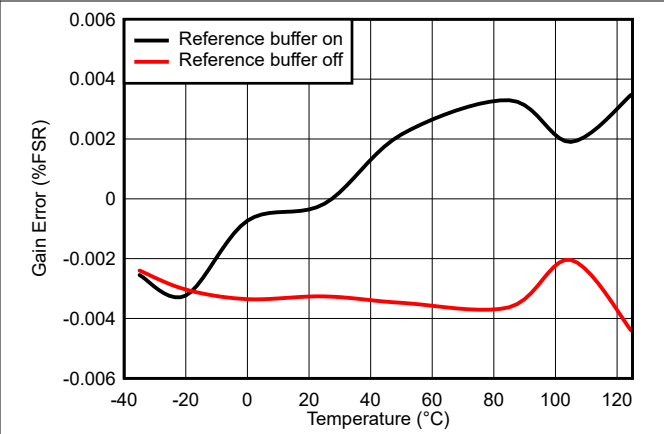


Figure 5-24. Gain Error vs Temperature

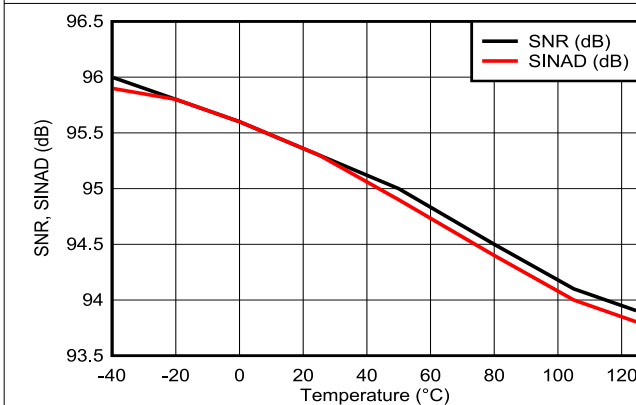


Figure 5-25. SNR and SINAD vs Temperature

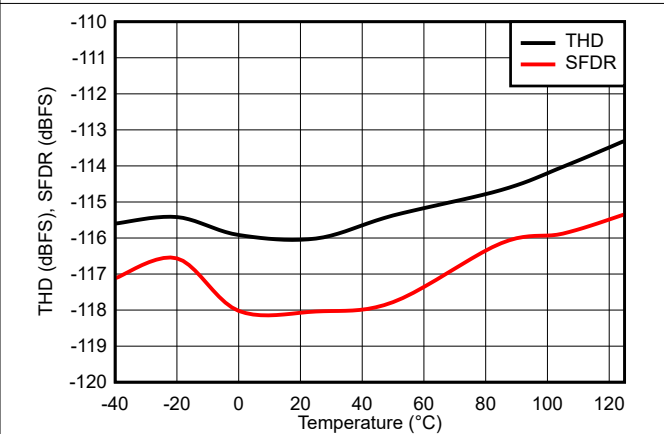
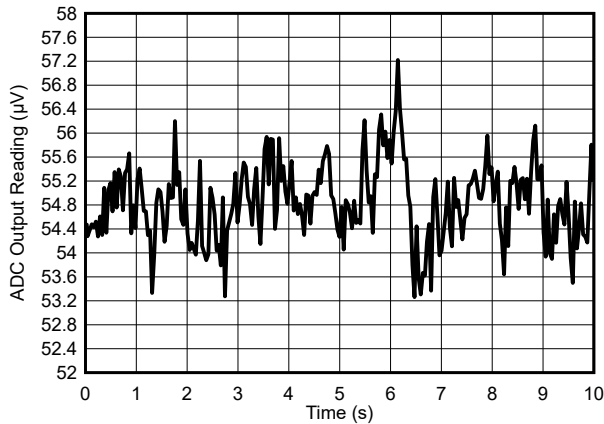


Figure 5-26. THD and SFDR vs Temperature

5.11 Typical Characteristics (continued)

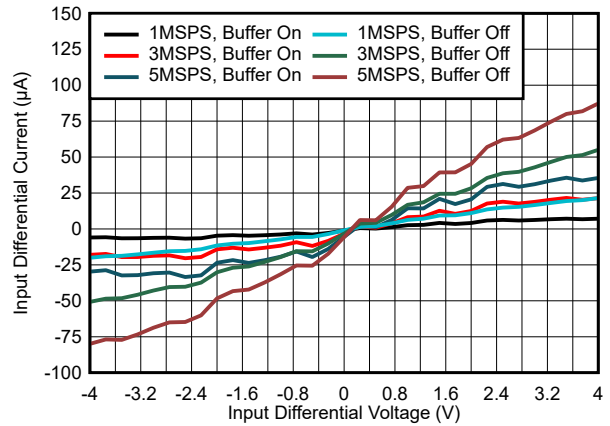
at $T_A = 25^\circ\text{C}$, $AVDD = 5\text{V}$, $VDD_1V8 = 1.8\text{V}$, external $V_{REF} = 4.096\text{V}$, and maximum throughput (unless otherwise noted)

Each curve corresponds to a ADS931x unit under test.



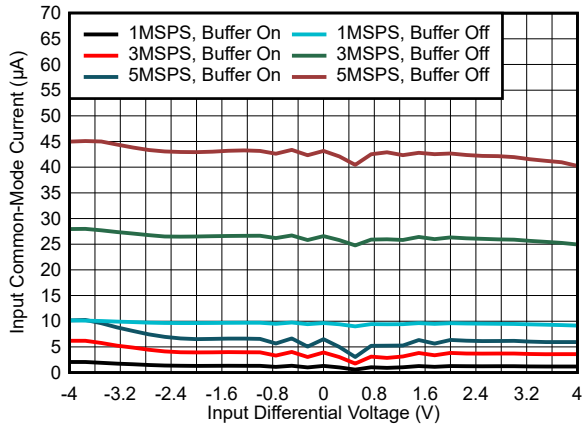
1.6MSPS sampling rate, 65,536 samples averaged per reading, LFN_COMP = 40A1h

Figure 5-27. 1/f Noise for 0.1Hz to 10Hz Bandwidth



See the INT_BUFFER register field description

Figure 5-28. Differential Analog Input Current vs Input Differential Voltage



See the INT_BUFFER register field description

Figure 5-29. Common-Mode Analog Input Current vs Input Differential Voltage

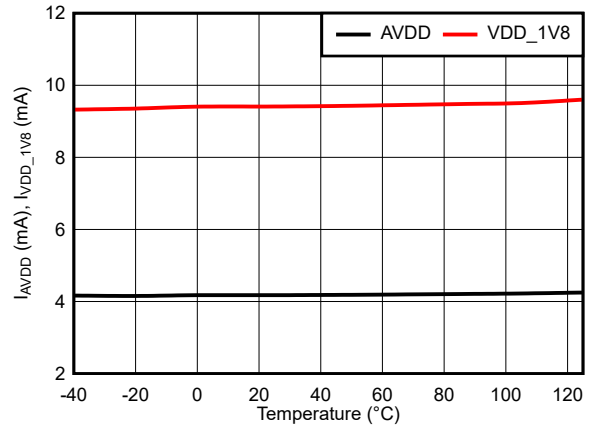


Figure 5-30. AVDD and VDD_1V8 Current vs Temperature

5.11 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $AVDD = 5\text{V}$, $VDD_1V8 = 1.8\text{V}$, external $V_{REF} = 4.096\text{V}$, and maximum throughput (unless otherwise noted)

Each curve corresponds to a ADS931x unit under test.

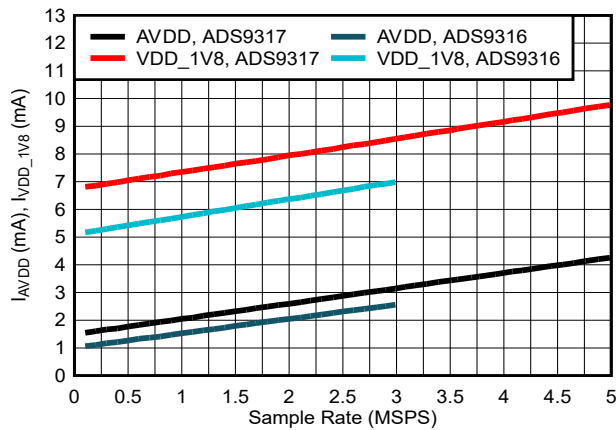


Figure 5-31. AVDD and VDD_1V8 Current vs Sample Rate

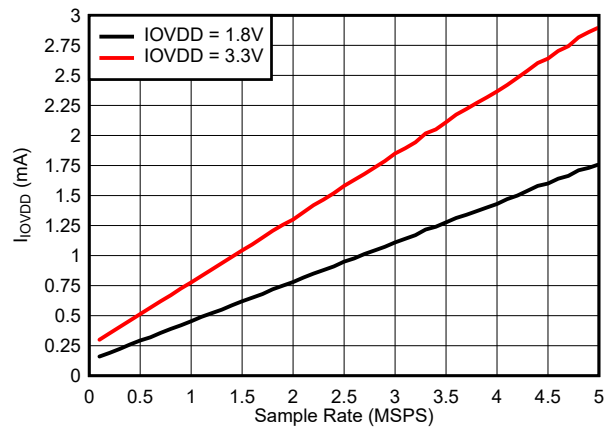


Figure 5-32. IOVDD Current vs Sample Rate

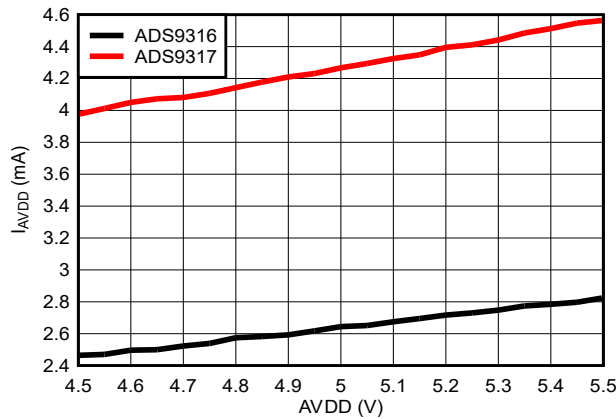


Figure 5-33. AVDD Current vs AVDD Voltage With High AVDD

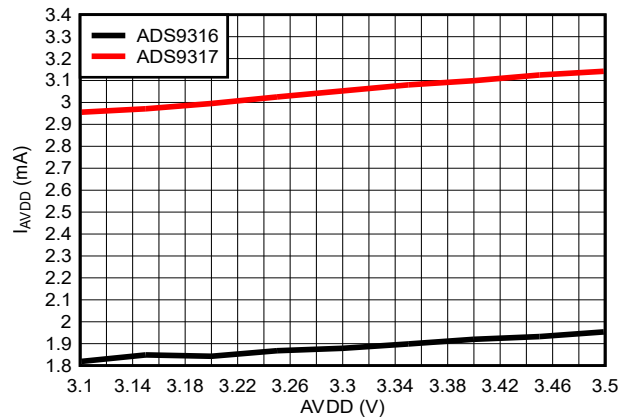


Figure 5-34. AVDD Current vs AVDD Voltage With Low AVDD

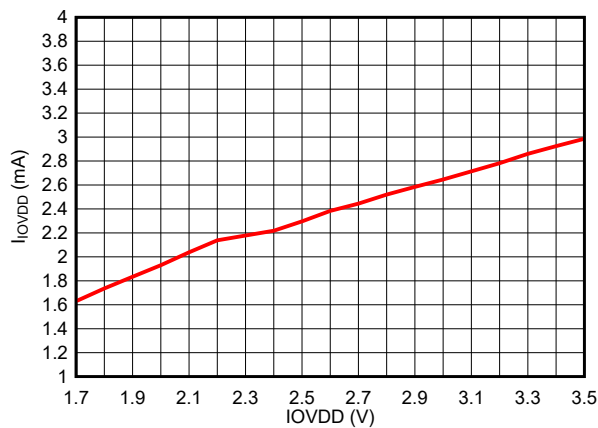


Figure 5-35. IOVDD Current vs IOVDD Voltage

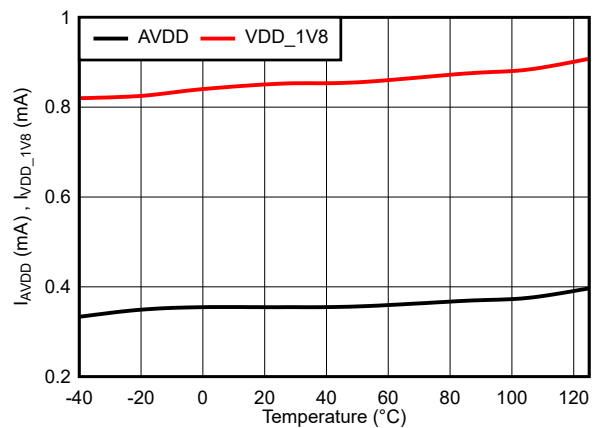


Figure 5-36. AVDD and VDD_1V8 Power-Down Current vs Temperature

5.11 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $AVDD = 5\text{V}$, $VDD_{1V8} = 1.8\text{V}$, external $V_{REF} = 4.096\text{V}$, and maximum throughput (unless otherwise noted)

Each curve corresponds to a ADS931x unit under test.

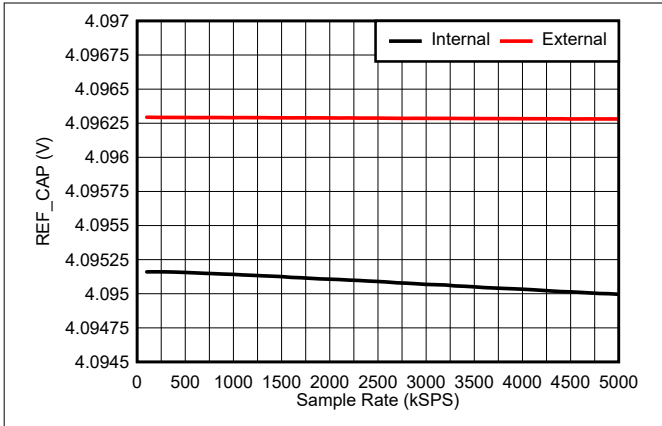


Figure 5-37. REF_CAP vs Sample Rate With 4.096V Reference

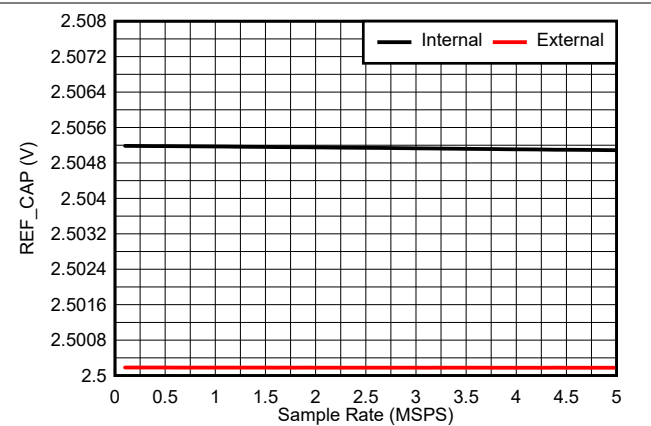


Figure 5-38. REF_CAP vs Sample Rate With 2.5V Reference

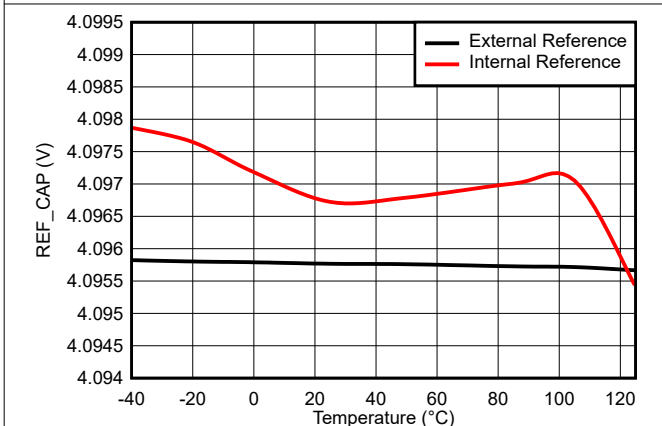


Figure 5-39. REF_CAP Voltage vs Temperature

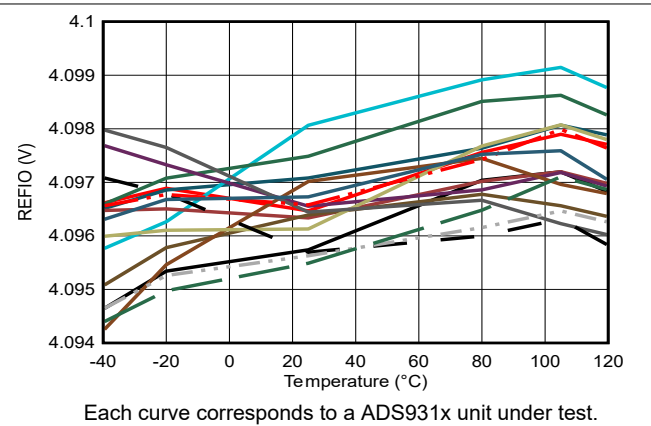


Figure 5-40. REFIO Voltage vs Temperature With 4.096V Internal Reference

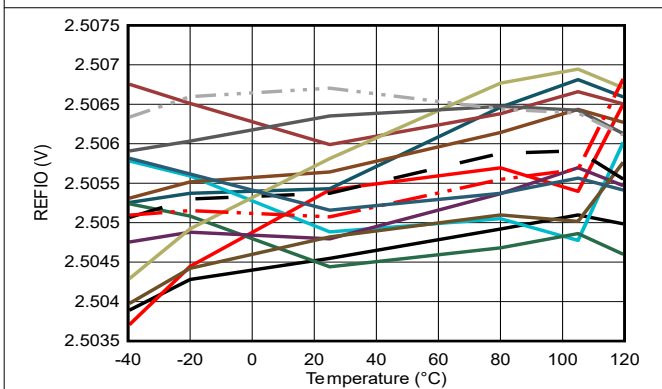


Figure 5-41. REFIO Voltage vs Temperature With 2.5V Internal Reference

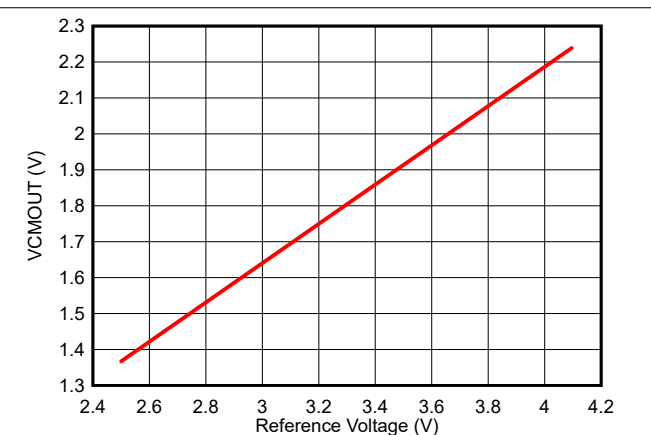


Figure 5-42. VCMOUT Voltage vs Reference Voltage

5.11 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $AVDD = 5\text{V}$, $VDD_{1V8} = 1.8\text{V}$, external $V_{REF} = 4.096\text{V}$, and maximum throughput (unless otherwise noted)

Each curve corresponds to a ADS931x unit under test.

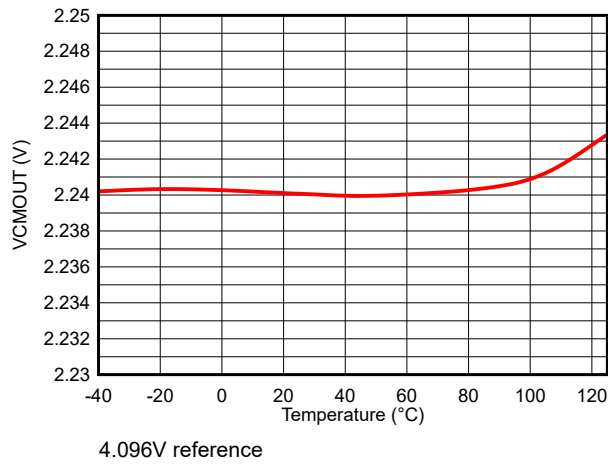


Figure 5-43. VCMOUT Voltage vs Temperature With 4.096V Reference

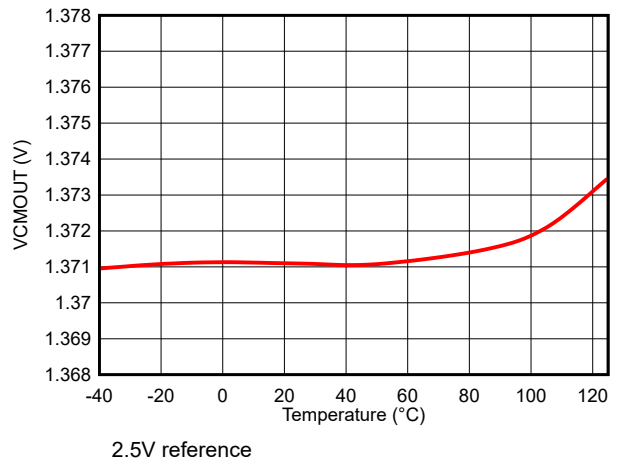


Figure 5-44. VCMOUT Voltage vs Temperature With 2.5V Reference

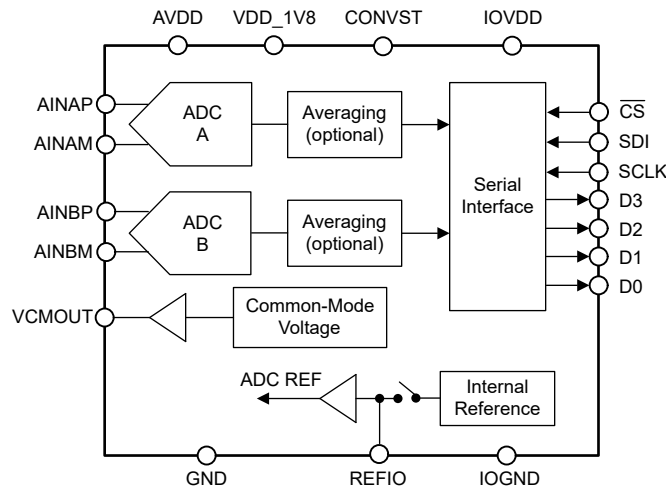
6 Detailed Description

6.1 Overview

The ADS931x (ADS9316, ADS9317) is a family of 18-bit, dual, simultaneous-sampling, analog-to-digital converters (ADCs) with an integrated reference. The ADS931x supports unipolar, differential analog input signals and features built-in data averaging.

The ADS931x provides a simple, serial interface to the host controller and operates over a wide range of analog and digital power supplies. The serial interface is compatible with traditional SPI protocols and supports daisy-chain connection.

6.2 Functional Block Diagram



6.3 Feature Description

6.3.1 Analog Inputs

This device supports unipolar, differential, analog input signals. Figure 6-1 shows a small-signal equivalent circuit of the sample-and-hold circuit. Each sampling switch is represented by a resistance (R_{S1} and R_{S2} , typically 25Ω) in series with sampling switches (SW_1 and SW_2). The sampling capacitors, C_{S1} and C_{S2} , are typically 18pF .

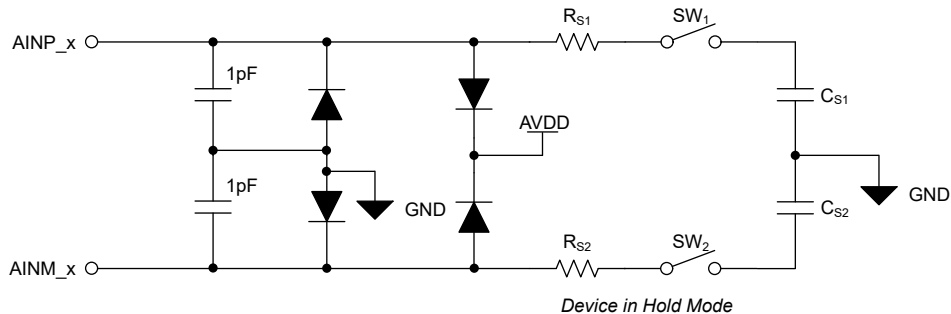


Figure 6-1. Analog Inputs

6.3.2 Reference

The ADS931x has a precision, low-drift voltage reference internal to the device. For best performance, filter the internal reference noise by connecting a 1µF ceramic bypass capacitor to the REFIO pin. On power-up, as described in [Table 6-1](#), the internal reference is active.

Table 6-1. Reference Source Selection

PD_REF REGISTER VALUE	ADC REFERENCE SOURCE
00b (default)	Internal reference is active.
01b	Reserved.
10b	Internal reference is active.
11b	Internal reference is inactive. Force an external reference with REFIO (pin 9).

6.3.2.1 Internal Reference

The ADS931x features an internal reference voltage with a nominal output voltage of 4.096V when AVDD = 5V and 2.5V when AVDD = 3.3V. The internal reference is active on power-up. As shown in [Figure 6-2](#) and [Figure 6-3](#), place a minimum 1µF decoupling capacitor between the REFIO and REF_M pins.

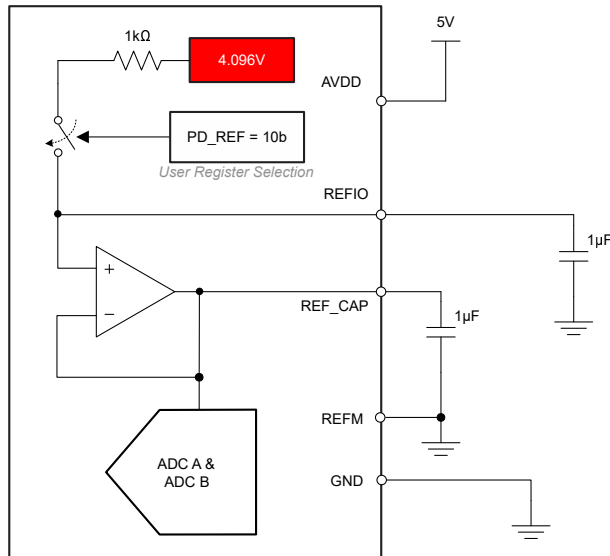


Figure 6-2. Internal Reference: AVDD = 5V

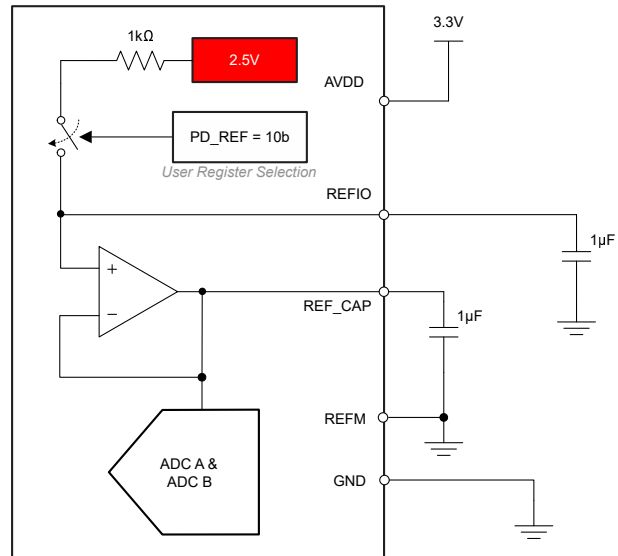


Figure 6-3. Internal Reference: AVDD = 3.3V

6.3.2.1.1 Selectable Internal Reference with 5V AVDD

When AVDD = 5V, the ADS931x offers a selectable internal reference value of 4.096V, 3.3V, or 2.5V. Select the internal reference value by writing to INT_REF_MODE in register bank 1 as shown in [Table 6-2](#).

Table 6-2. Internal Reference Selection when AVDD = 5V

Internal Reference Value	INT_REF_MODE
4.096V	0b
3.3V	11b
2.5V	1b

6.3.2.2 External Reference

Connect an external reference voltage, as shown in Figure 6-4, at the REFIO pin with an appropriate decoupling capacitor placed between the REFIO and REF_CAP pins. For improved thermal drift performance, use the REF7040. To disable the internal reference, set PD_REF = 11b in address 0x0C in register bank 1 as described in the Reference section. The REFIO pin has electrostatic discharge (ESD) protection diodes connected to the AVDD and REFM pins.

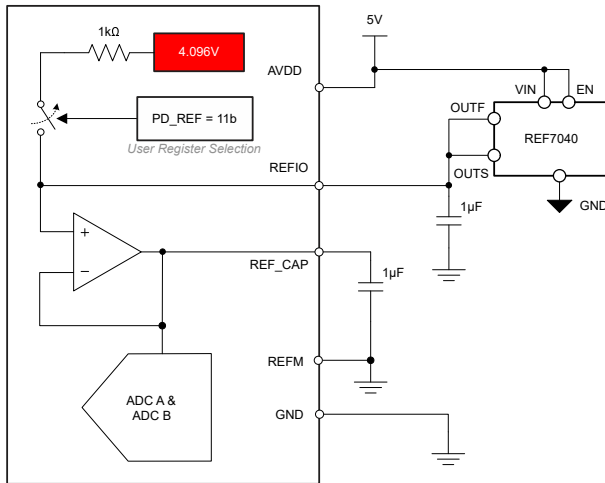


Figure 6-4. External Reference: AVDD = 5V

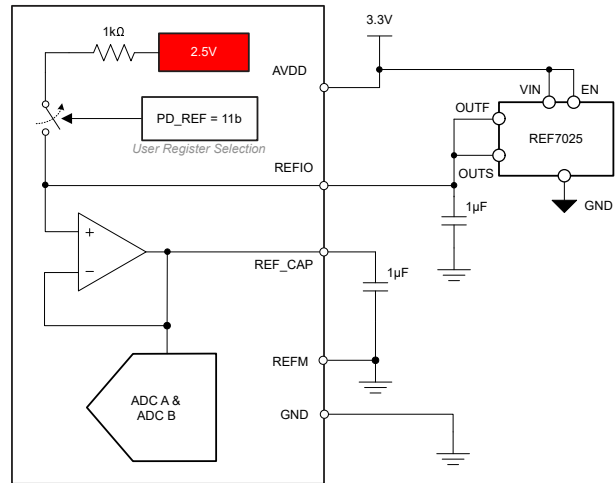


Figure 6-5. External Reference: AVDD = 3.3V

6.3.2.3 External Reference With External Reference Buffer

To improve system gain error thermal drift, power off the internal device reference buffer and connect an external, low-drift reference buffer to the device. As illustrated in Figure 6-6, connect the output of the external reference buffer to the REFIO and REF_CAP pins and power down the internal reference buffer. Make sure the connection to REF_CAP is less than 2Ω. Figure 6-7 shows the current drawn on the REF_CAP pin versus the differential analog input voltage with varying sample rates. Table 6-3 describes the sequence to power down the internal reference buffer.

Table 6-3. Sequence to Power Down the Internal Reference Buffer

FRAME NUMBER	REGISTER		DESCRIPTION
	ADDRESS	VALUE[15:0]	
1	0x02	0x0002	Select register bank 1
2	0x0C	0x0300	Power down the internal reference
3	0x13	0x0008	Power down the internal reference buffer
4	0x02	0x0002	Select register bank 1

- N = Device resolution

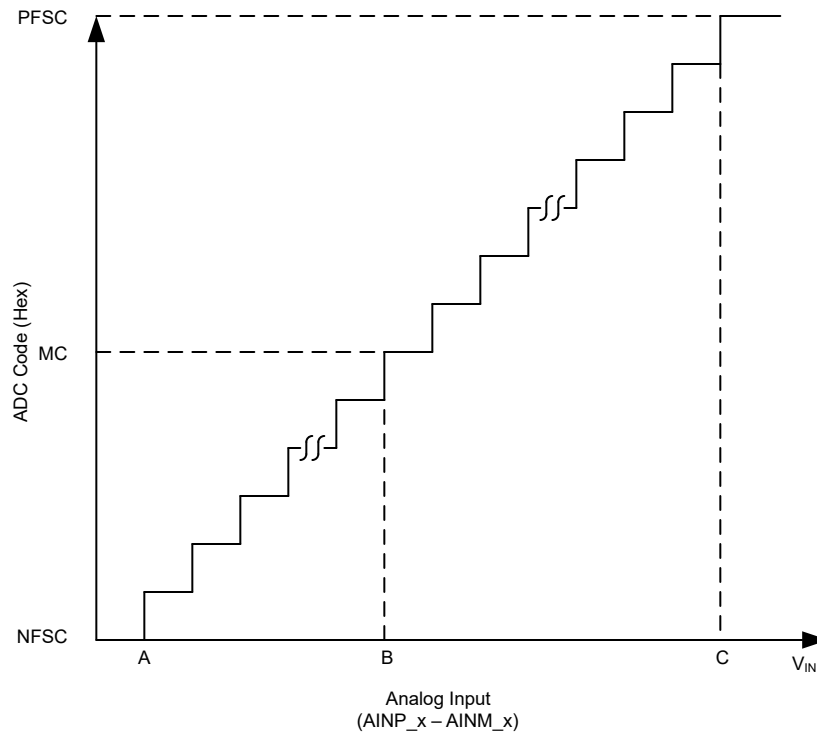


Figure 6-9. Transfer Characteristics

Table 6-4. Transfer Characteristics

STEP	INPUT VOLTAGE (AINP_x - AINM_x)	CODE	DESCRIPTION	18-BIT OUTPUT CODE (Two's Complement)	18-BIT OUTPUT CODE (Straight Binary)
A	$\leq -(V_{REFIO} + 1\text{LSB})$	NFSC	Negative full-scale code	0x20000	0x00000
B	$0V + 1\text{LSB}$	MC	Mid-code	0x00000	0x20000
C	$\geq (V_{REFIO} - 1\text{LSB})$	PFSC	Positive full-scale code	0x1FFFF	0x3FFFF

6.3.5 Programmable Data Averaging Filter

The ADS931x features two built-in decimation filters that average the conversion results from the ADC:

- Simple average: The ADC output is the average of the conversion results in a fixed window size and the output data rate decreases with an increased window size.
- Moving average: The ADC output is the average of the conversion results in a moving window size. The output data rate stays constant with an increased window size.

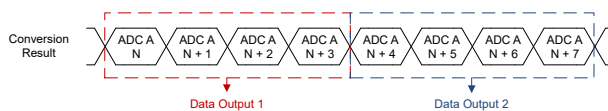


Figure 6-10. Simple Average Data Output



Figure 6-11. Moving Average Data Output

6.3.5.1 Simple Average

To enable simple data averaging, write 1b to SAVG_EN in address 0x0D and select the window size by writing to SAVG_MODE in address 0x0D.

Table 6-5 specifies the improvement in SNR with simple data averaging and the corresponding impact on ADC output rate. Figure 6-12 illustrates the ADC output timing for a simple average of four samples.

Table 6-5. Simple Average - ADC Output Data Rate and SNR vs Data Averaging

OVERSAMPLING RATIO	SNR - ADS9317 (18-BIT)	MAXIMUM OUTPUT DATA RATE
No averaging	95.4dB	5MSPS
2	98.6dB	2.5MSPS
4	101.3dB	1.25MSPS
8	104.1dB	625kSPS
16	106.9dB	312.5kSPS
32	109.6dB	156.25kSPS
64	112.1dB	78.125kSPS
128	114.6dB	39.0625kSPS

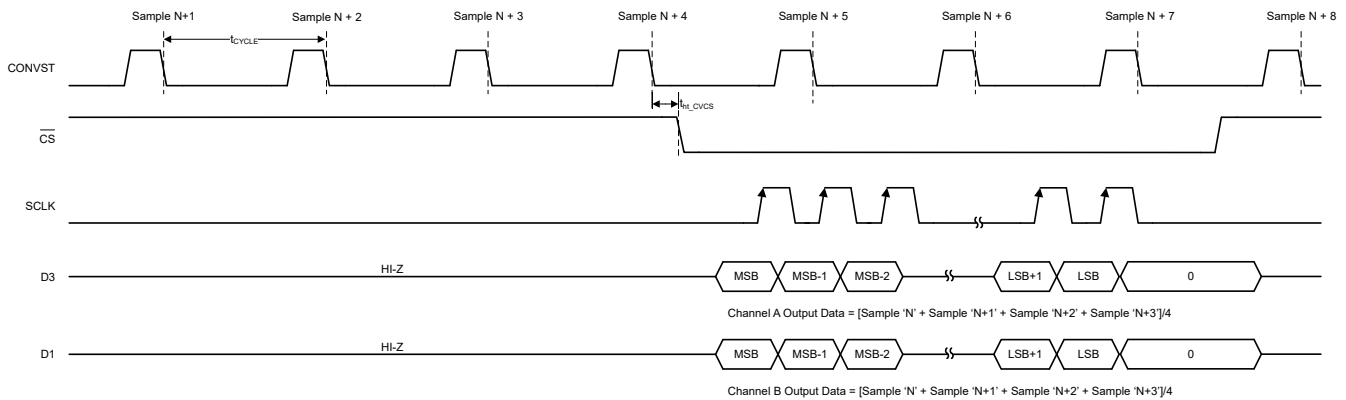


Figure 6-12. ADC Output Example for Simple Average of 4 Samples in 2-Lane Data Interface Mode

The ADS931x supports simple averaging with low latency mode enabled. Figure 6-13 illustrates the timing diagram when simple averaging is used with low latency mode active.

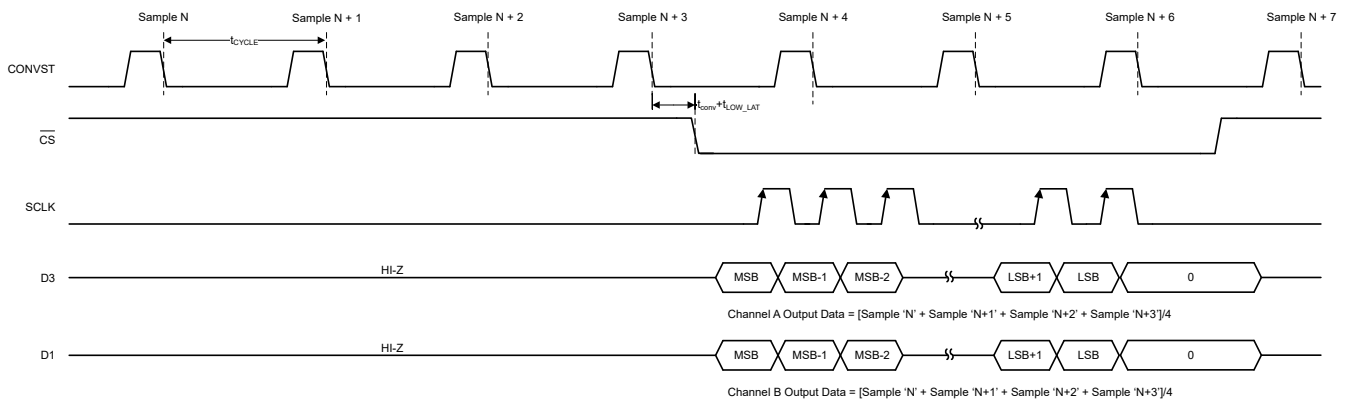


Figure 6-13. ADC Output Example for Simple Average of 4 Samples in 2-Lane Data Interface Mode with Low Latency Mode Enabled

6.3.5.1.1 Simple Average with Noncontinuous CONVST

To enable averaging with a non-continuous CONVST, follow the sequence in Table 6-6.

Table 6-6. Simple Average Initialization Sequence for Non-continuous CONVST

Step	Description
1	Unlock the device register map.
2	Enable simple average by writing 1b to SAVG_EN and selecting the window size in SAVG_MODE.
3	Write 1b to AVG_SYNC.

Table 6-6. Simple Average Initialization Sequence for Non-continuous CONVST (continued)

Step	Description
4	Wait 100µs.
5	Provide 2 additional pulses of CONVST.

Figure 6-14 illustrates the timing to enable simple averaging for an average of 2 samples with a noncontinuous CONVST with default timing.

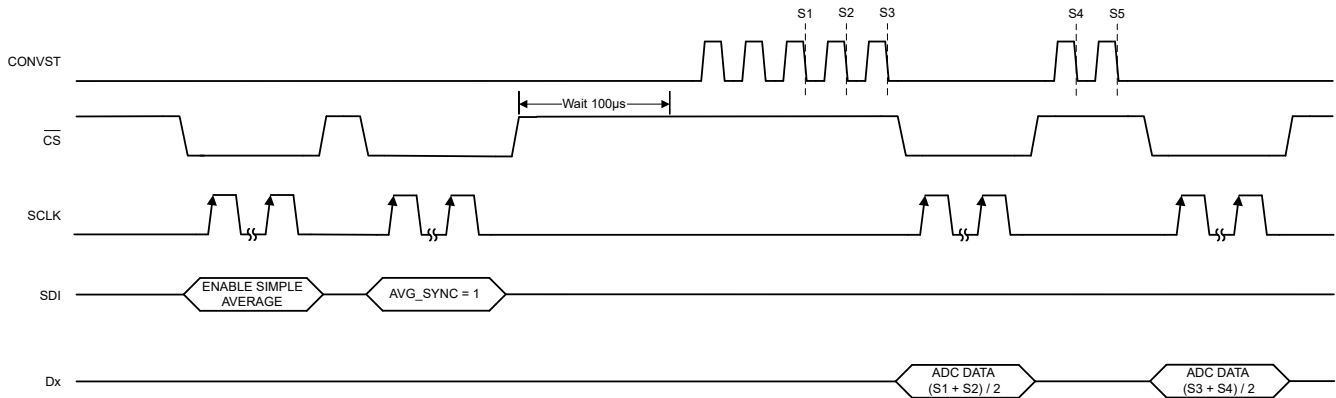


Figure 6-14. Simple Average Enable Sequence Timing with Noncontinuous CONVST for Average of 2 Samples

ADS931x also supports simple averaging with noncontinuous CONVST in low latency mode. Figure 6-15 illustrates the timing for implementing simple averaging with a noncontinuous CONVST signal in low latency mode.

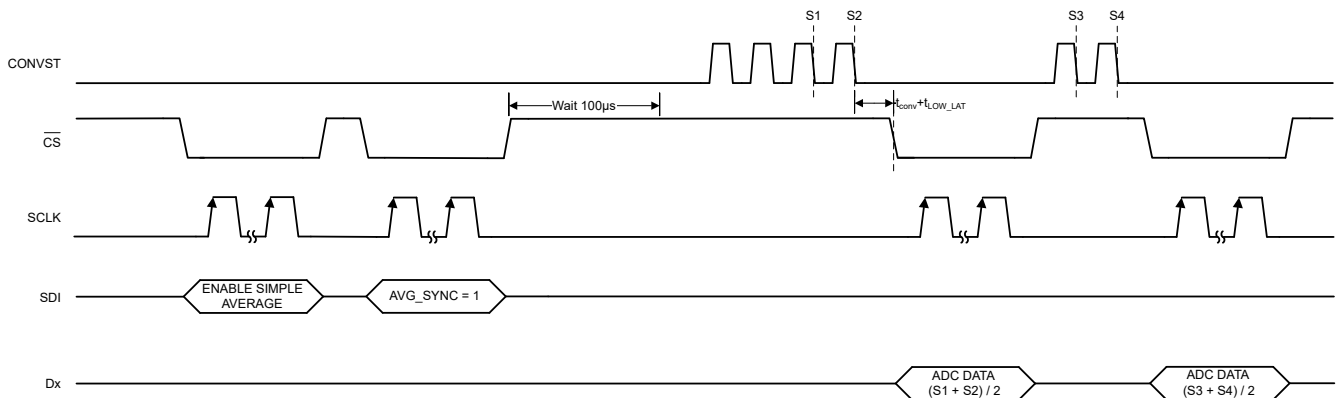


Figure 6-15. Simple Average Enable Sequence Timing with Noncontinuous CONVST in Low Latency Mode

6.3.5.2 Moving Average

To enable moving data averaging, select the averaging window size by writing to MAVG_MODE in address 0x0D. in register bank 1. The moving average window size is user-selectable between 2, 4, and 8 conversions.

Table 6-7 specifies the improvement in SNR with moving data averaging. Figure 6-16 illustrates the ADC output timing for a moving average of four samples.

Table 6-7. Moving Average - ADC Output Data Rate and SNR vs Data Averaging

OVERSAMPLING RATIO	SNR - ADS9317 (18-BIT)	MAXIMUM OUTPUT DATA RATE
No averaging	95.4dB	5MSPS
2	98.5dB	5MSPS

Table 6-7. Moving Average - ADC Output Data Rate and SNR vs Data Averaging (continued)

OVERSAMPLING RATIO	SNR - ADS9317 (18-BIT)	MAXIMUM OUTPUT DATA RATE
4	100.8dB	5MSPS
8	102.9dB	5MSPS

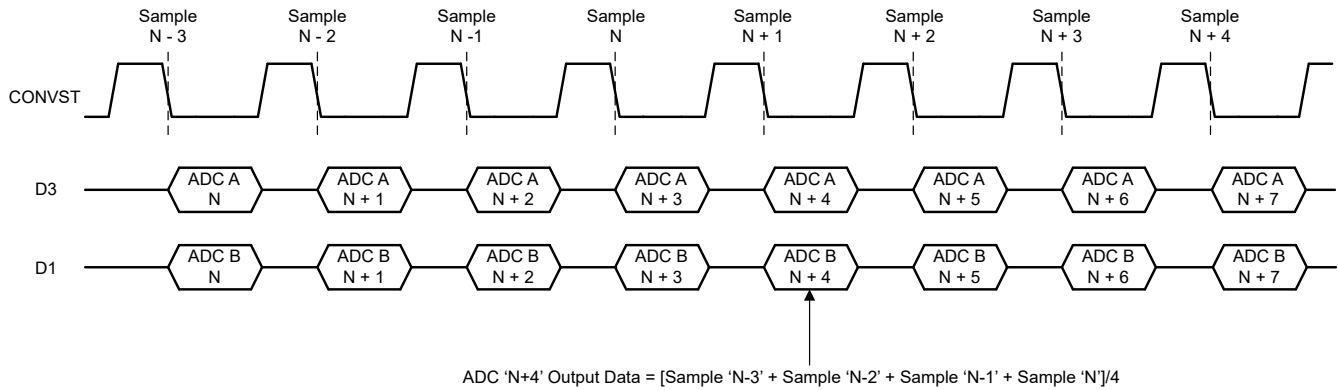


Figure 6-16. ADC Output Example for a Moving Average of 4 Samples

6.3.6 Channel Averaging

The ADS931x supports channel averaging to create a lower noise output from the original channel data. When channel averaging is enabled, the ADC data output width does not change. In typical use, the signal is applied in parallel to both channels of the device as shown in [Figure 6-17](#). To enable channel averaging, write 1b to CH_AVERAGE in address 0x0D. When enabled, the data output is the average of channel A and channel B. The device output on the data interface corresponding to channel A is identical to the data corresponding to channel B. Either channel A or channel B data can be used to evaluate the conversion result.

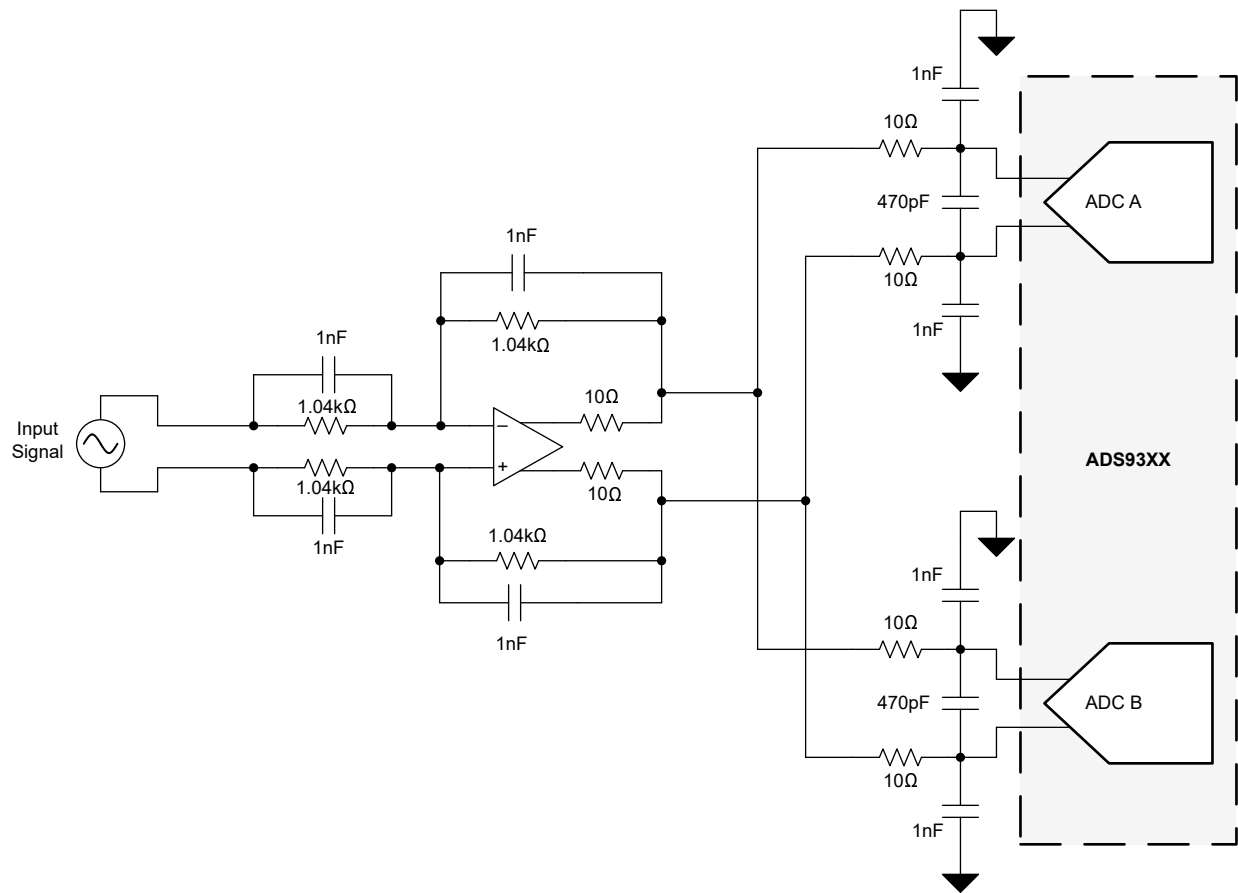


Figure 6-17. Channel Averaging Hardware Connection

6.3.7 Common-Mode Voltage Output

The ADS931x offers a common-mode voltage output used to set the voltage output common-mode on external circuits such as fully-differential amplifiers. As described in [Table 6-8](#), the device has the ability to program the common-mode output voltage by writing to VCMOUT_SEL in address 0x39.

[Equation 2](#) shows how to calculate the VCMOUT voltage based on the reference voltage and VCMOUT_SEL register field.

$$VCMOUT = \left(0.546 \times V_{REF}\right) + \left(0.064 \times VCMOUT_FACTOR \times \frac{V_{REF}}{4.096}\right) \quad (2)$$

Table 6-8. VCMOUT Programmability with 4.096V Reference

VCMOUT_SEL	VCMOUT_FACTOR	MIN	TYP	MAX
000b	0	2.21V	2.23V	2.25V
001b	-1	2.15V	2.17V	2.19V
010b	-2	2.09V	2.11V	2.13V
011b	-3	2.02V	2.04V	2.06V
100b	4	2.47V	2.49V	2.51V
101b	3	2.41V	2.43V	2.45V
110b	2	2.34V	2.36V	2.38V
111b	1	2.27V	2.29V	2.31V

6.3.8 ADC Output Data Randomizer

The ADS931x features a data output randomizer. When enabled, the ADC conversion result is bit-wise exclusive-ORed (XOR) with the four pseudo-random binary sequence (PRBS) bits appended to the ADC data output. See the [Data Frame Width](#) section. The XOR PRBS bits have equal probability of being either 1 or 0. As a result of the XOR operation, the data from the ADS931x is randomized. The ground bounce created by the transmission of this randomized result over the data interface is uncorrelated with the analog input voltage. This uncorrelated transmission helps minimize interference between data transmission and analog performance of the ADC when the PCB layout does not minimize ground bounce. To enable the output data randomizer, write 01111b to XOR_EN in address 0x0D in register bank 1. [Figure 6-18](#) shows the data output when the data output randomizer is enabled.

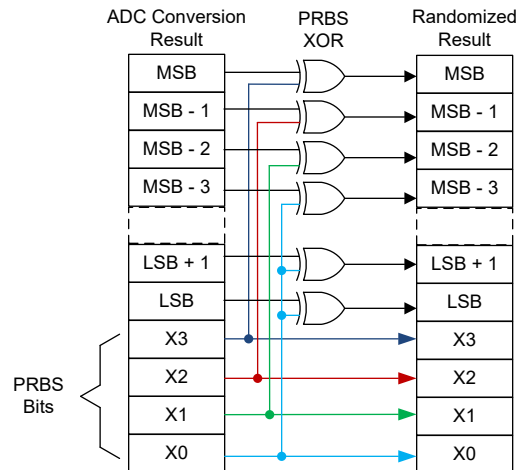


Figure 6-18. XOR Operation With 4-Bit PRBS

6.4 Device Functional Modes

6.4.1 Reset

Reset the ADS931x by writing 1b to the RESET field in address 0x01. The device registers are initialized to the default values after reset.

6.4.2 Normal Operation

In normal operating mode, the ADS931x is powered up and digitizes sample N on the falling edge of CONVST. Data corresponding to sample N – 1 is launched on the digital interface on the falling edge of \overline{CS} as illustrated in [Figure 5-2](#).

6.4.3 Low-Latency Mode

In low-latency mode, the conversion for sample N starts on the falling edge of CONVST. Data corresponding to sample N are launched on the digital interface on the falling edge of \overline{CS} . As illustrated in [Figure 5-3](#), the host provides a minimum time of $t_{CONV} + t_{LOW_LAT}$ between the falling edges of CONVST and \overline{CS} . To enter low-latency mode, write 1b to LATENCY_MODE in address 0x09.

6.4.4 \overline{CS} -CONVST Short Mode

In \overline{CS} -CONVST short mode, tie \overline{CS} and CONVST together externally. As illustrated in [Figure 5-4](#), the ADS931x digitizes sample N on the falling edge of CONVST. Data corresponding to sample N – 1 are launched on the digital interface on the falling edge of \overline{CS} . \overline{CS} -CONVST short mode is supported by default and creates a 5ns internal delay between the falling edge of CONVST and \overline{CS} . The internal delay between CONVST and \overline{CS} is disabled by writing 1b to CSZ_CONVST_DELAY_DIS in address 0x13.

6.4.5 Register Read Mode

In register read mode, the device launches the requested device register data on D3. To enter register read mode, set DATA_SEL = 1b as described in the [Register Read](#) section.

6.4.6 Initialization Sequence

The ADS931x is designed to support a wide range of signal input common-modes. To set the voltage output common-mode on external circuits, the device provides a voltage output on the VCMOUT pin, which matches the expected input common-mode of the device. If the input signal common-mode is equal to the default VCMOUT (VCMOUT_SEL = 0b), no initialization sequence is required.

If the input signal common-mode is set to a value other than the default VCMOUT, program the VCMOUT_SEL register field to the equivalent value. After VCMOUT_SEL is programmed to the device, provide 800 cycles of CONVST. [Table 6-9](#) shows the steps to initialize the device if the input signal common-mode does not match the default value of VCMOUT.

Table 6-9. ADS931x Initialization Sequence

STEP NUMBER	DESCRIPTION
1	Unlock the register map.
2	Select the value of VCMOUT by writing to VCMOUT_SEL.
3	Lock the register map.
4	Provide 800 cycles of CONVST.

6.5 Programming

6.5.1 Data Interface

The ADS931x features an SPI-compatible serial interface with 1-lane, 2-lane, and 4-lane options for the data output. [Table 6-10](#) shows the register settings to configure the number of output data lanes and the corresponding ADC conversion data output on each serial data output pin.

Table 6-10. Output Data Interface Configuration Settings

NUMBER OF OUTPUT DATA LANES	NUM_DATA_LANES REGISTER VALUE	SERIAL DATA OUTPUT PIN	ADC CONVERSION DATA OUTPUT
4 lanes	000b	D3	ADC A[17:8]
		D2	ADC A[7:0], 0b00
		D1	ADC B[17:8]
		D0	ADC B[7:0], 0b00
2 lanes	101b	D3	ADC A[17:0], 0b00
		D2	Hi-Z
		D1	ADC B[17:0], 0b00
		D0	Hi-Z
1 lane	110b	D3	ADC A[17:0], 0b000000, ADC B[17:0], 0b000000
		D2	Hi-Z
		D1	Hi-Z
		D0	Hi-Z

6.5.2 Data Frame Width

The ADS931x supports 20-bit, and 24-bit data frame width options. The default output data frame width is 20 bits. As shown in [Table 6-11](#), the output data frame width increases to 24 bits depending on the use of XOR.

Table 6-11. Output Data Frames

SAVG_EN	XOR_EN	OUTPUT WIDTH (Bits)	OUTPUT DATA FRAME
No averaging	XOR disabled	20	{Conversion result [17:0], 0b00}
	XOR enabled	24	{Conversion result [17:0], PRBS[3:0], 0b00}
Averaging enabled	XOR disabled	20	{Conversion result [19:0]}
	XOR enabled	24	{Conversion result [19:0], PRBS[3:0]}

6.5.3 SPI Modes

The device supports SPI-compatible protocols with all combinations of clock phase and polarity. [Table 6-12](#) provides the details of the SPI protocols that the device supports.

Table 6-12. SPI Protocols

PROTOCOL	SPI_MODE REGISTER FIELD	SCLK POLARITY (At \overline{CS} Falling Edge)	MSB LAUNCH EDGE	SCLK LAUNCH EDGE	SDI LATCH EDGE	TIMING DIAGRAM
SPI-00	00b	Low	\overline{CS} falling	Rising	Rising	Figure 6-19
SPI-01	01b	Low	1 st SCLK rising	Rising	Falling	Figure 6-20
SPI-10	10b	High	\overline{CS} falling	Falling	Falling	Figure 6-19
SPI-11	11b	High	1 st SCLK falling	Falling	Rising	Figure 6-20

[Figure 6-19](#) and [Figure 6-20](#) show the timing diagrams for the SPI protocols.

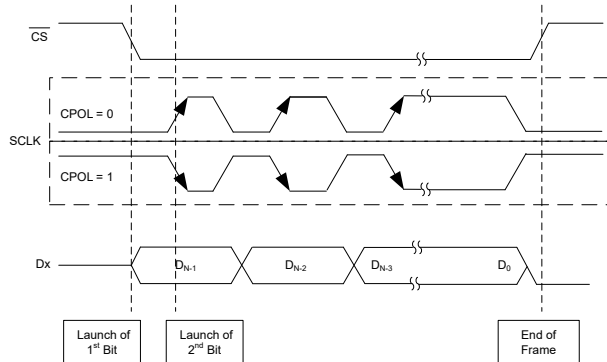


Figure 6-19. SPI-00 and SPI-10 Protocols

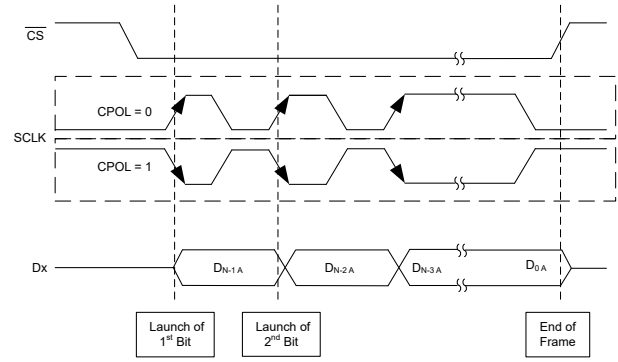


Figure 6-20. SPI-01 and SPI-11 Protocols

6.5.4 CONVST Inversion

In default operation, the ADS931x initiates the conversion on the falling edge of CONVST. The device offers the ability to invert CONVST so that the device initiates the ADC conversion on the rising edge of CONVST. To enable this mode, write 1b to CONVST_INVERT in address 0x14. Figure 6-21 illustrates the timing when CONVST is inverted. If low latency mode is enabled, verify that t_{ph_CV} is greater than $t_{CONV} + t_{LOW_LAT}$, so that the ADC output is from the current ADC sample.

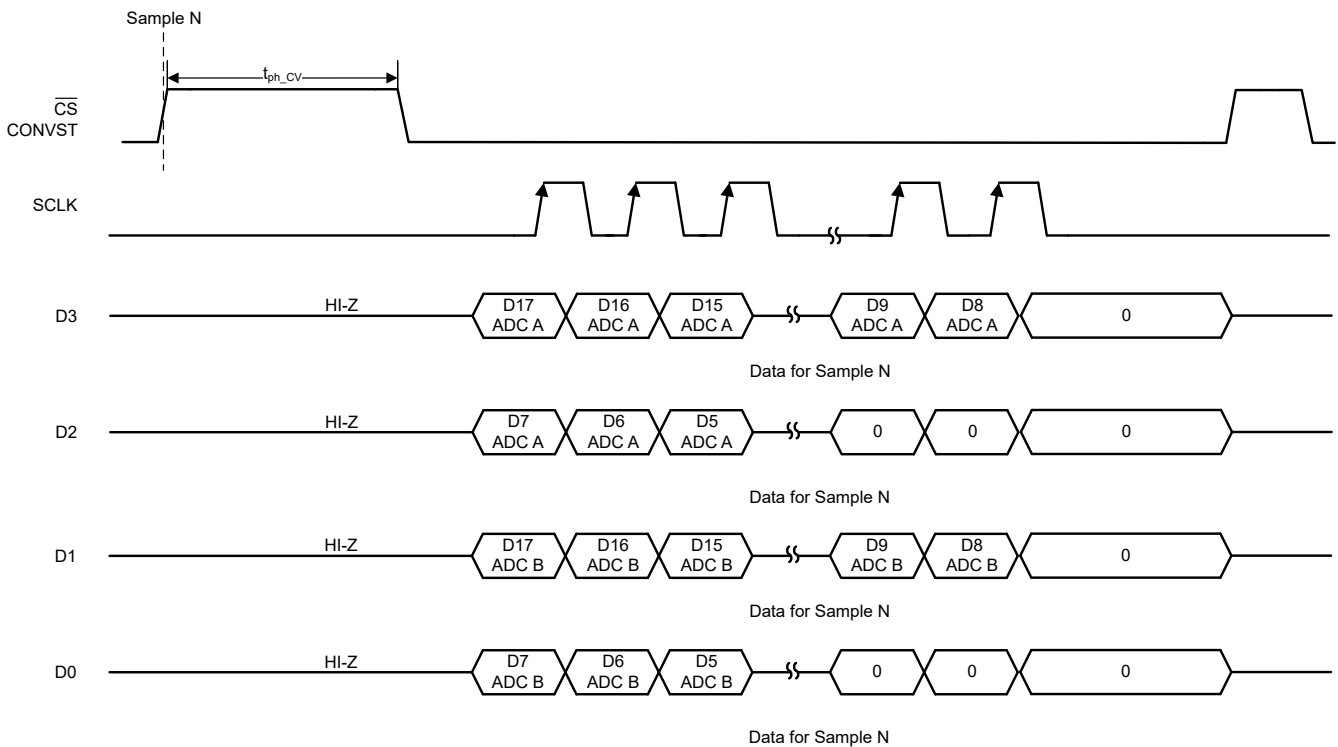


Figure 6-21. CONVST Inversion Timing

6.5.5 SCLK Echo Mode

To account for delays between the host and the ADC, the ADS931x features a SCLK Echo mode. In SCLK Echo mode, the device provides a return clock back to the host on pin D0 which can be used to latch the data as illustrated in Figure 6-22.

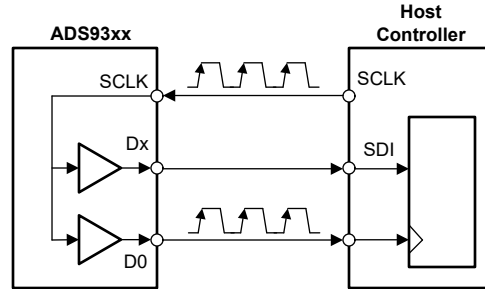


Figure 6-22. Signals Used for SCLK Echo Mode Data Transfer

SCLK Echo mode can be enabled in 1-lane or 2-lane data output mode. To enable the SCLK echo signal on D0, write 1b to SCLK_ECHO in address 0x9. If the device is in 2-lane data output mode, write 1b to SDO_PD_OVERRIDE in address 0xA. SCLK Echo mode is not compatible with 4-lane data output mode. [Figure 6-23](#) shows the timing for SCLK Echo mode.

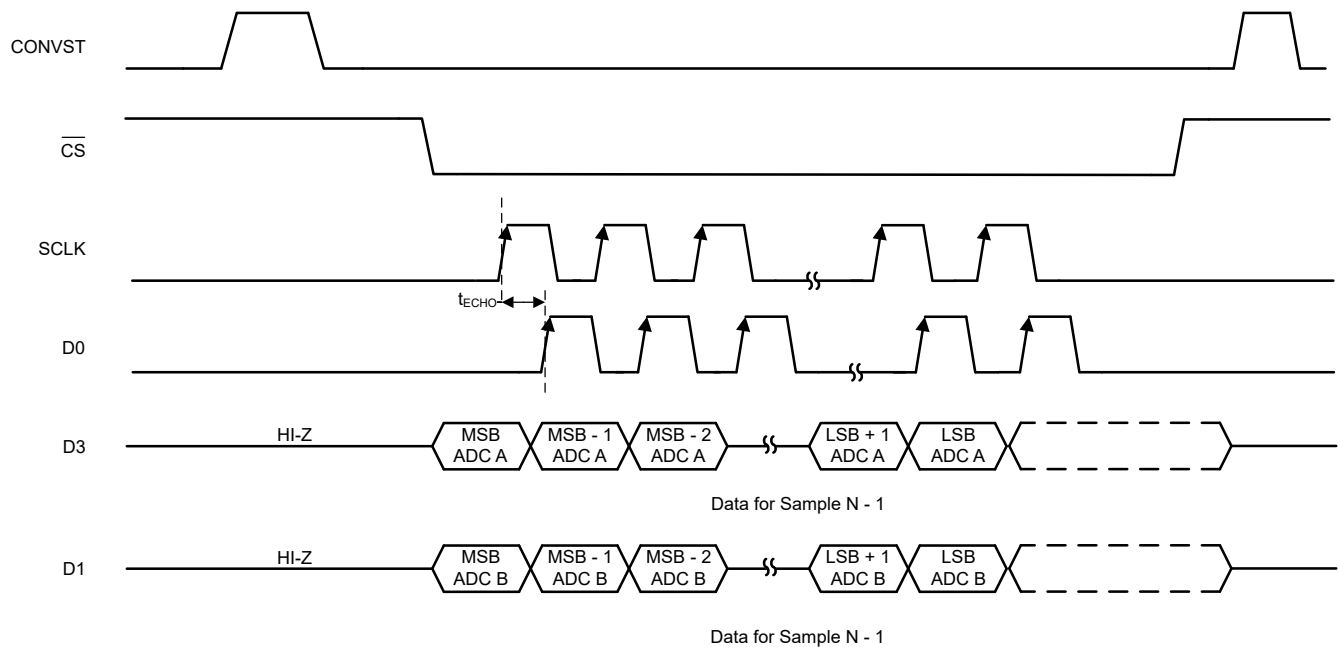


Figure 6-23. SCLK Echo Timing Diagram

6.5.6 Daisy-Chain Mode

The ADS931x operates either as a single converter or in a system with multiple converters. To take advantage of the simple, high-speed, SPI serial interface, cascade converters in a daisy-chain configuration when multiple converters are used. No register configuration is required to enable daisy-chain mode. [Figure 6-24](#) shows a typical connection of three converters in daisy-chain mode.

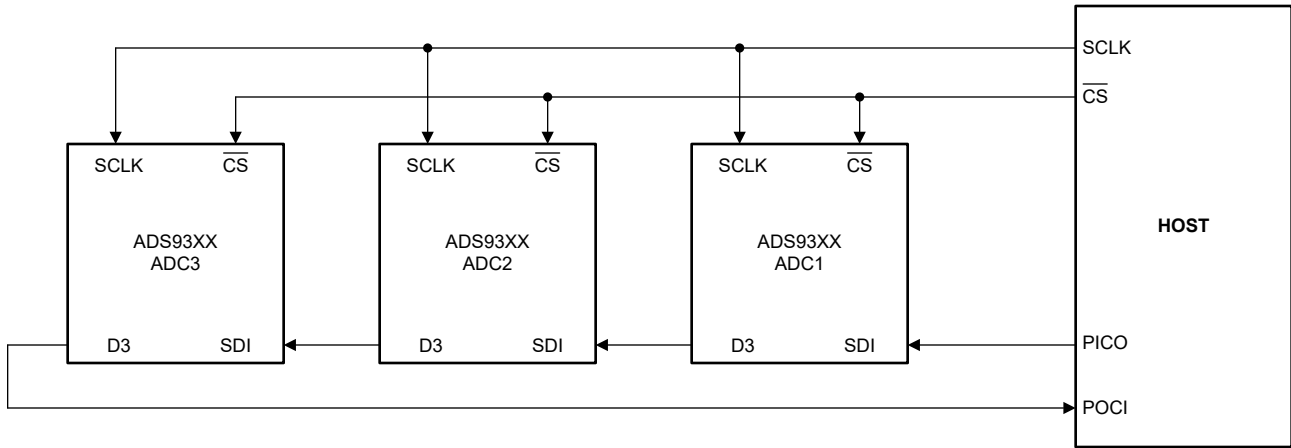


Figure 6-24. Daisy-Chain Connections

When the ADS931x is connected in daisy-chain mode, make sure the device operates in 1-lane interface mode by writing 110b to NUM_DATA_LANES. See the [Data Interface](#) section. The serial input data passes through the device with a 48 SCLK delay as long as \overline{CS} is active. [Figure 6-25](#) illustrates a detailed timing diagram of this mode when the conversion in each converter is performed simultaneously.

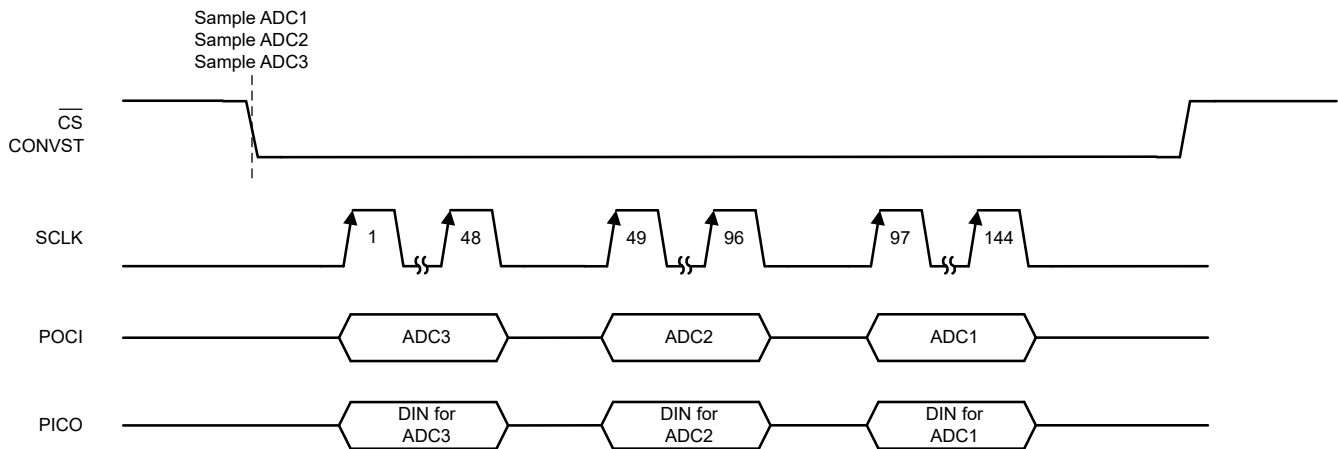


Figure 6-25. Simplified Daisy-Chain Timing

6.5.7 SPI Frame Length for Register Operations

As described in [Table 6-13](#), use a 24-bit or 48-bit SPI for register read or write operations, depending on the number of output data lanes used. If the SPI frame length is longer or shorter than required, this disparity results in unintentional writes to the user registers.

Table 6-13. SPI Frame Length Requirements

NUMBER OF OUTPUT DATA LANES	NUMBER OF SCLKS REQUIRED
4	24
2	24
1	24 or 48

6.5.8 Register Map Lock

The ADS931x implements a register map lock feature that prevents an accidental or unintended write to the device registers. By default, the device register map is locked. Unlock the register map by following the sequence shown in [Table 6-14](#) before writing or reading a register.

Table 6-14. ADS931x Register Map Unlock Sequence

STEP NUMBER	REGISTER		
	BANK	ADDRESS	VALUE[15:0]
1	0	0xFE	0xB38F
2	0	0xFE	0xABCD

After writing or reading registers, lock the register map to prevent unintended register writes. Writing any value other than the register map unlock sequence to address 0xFE locks the register map. [Table 6-15](#) shows an example sequence to lock the device register map.

Table 6-15. ADS931x Example Register Map Lock Sequence

STEP NUMBER	REGISTER		
	BANK	ADDRESS	VALUE[15:0]
1	0	0xFE	0x1234

6.5.9 Register Write

Register write access is enabled by following the register map unlock sequence described in the [Register Map Lock](#) section. The 16-bit registers are grouped in two register banks and are addressable with an 8-bit register address. Register bank 1 is selected for read or write operation by writing 0x02 to REG_BANK_SEL in address 0x02. Registers in bank 0 are always accessible, irrespective of the REG_BANK_SEL bits. The register addresses in bank 0 are unique and are not used in register bank 1. The 24-bit data on SDI consist of an 8-bit address and 16-bit data. The data on SDI are latched on the rising edge of SCLK. The device decodes the write command on the CS rising edge and updates the specified register with 16-bit data specified in the register write operation. [Figure 6-26](#) shows a 24-bit SPI frame for a register write and [Table 6-16](#) describes the steps required to write a register.

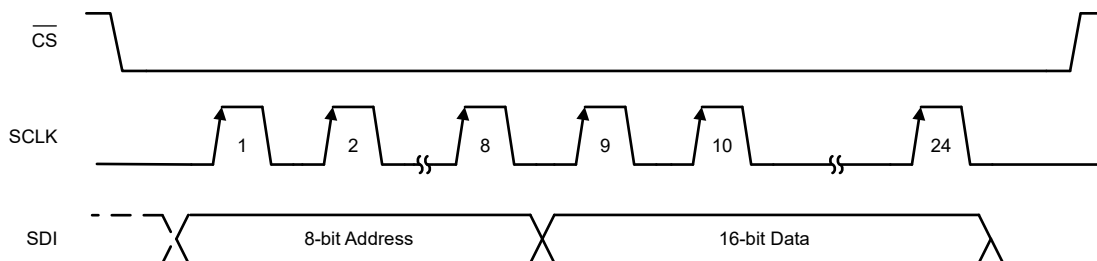


Figure 6-26. Register Write Frame

Table 6-16. Register Write Sequence

FRAME NUMBER	REGISTER		DESCRIPTION
	ADDRESS	VALUE[15:0]	
1	0xFE	0xB38F	Unlocks the register map.
2	0xFE	0xABCD	
3	0x02	0x02	Selects register bank 1. This step is only required for register bank 1.
4	REG_ADDR	DATA	Writes user data to the desired address. Repeat this step for the required number of register writes.
5	0xFE	0x1234	Locks the register map after register writes are completed.

6.5.10 Register Read

Register access is enabled by following the register map unlock sequence described in the [Register Map Lock](#) section. To read registers in bank 1, write 0x02 to register address 0x02. As shown in [Figure 6-27](#), 24-bit or 48-bit SPI frames are required to read registers. [Table 6-17](#) describes the sequence required to read a register. After the register map is unlocked and the register bank is selected, write the register address to be read to REG_READ_ADDR. Set DATA_SEL = 1 in address 0x01 to launch the register data on D3 in the next frame. On the rising edge of \overline{CS} , the read command is decoded and the requested register data are available for reading during the next frame. During the next frame, the first 16 bits on D3 correspond to the requested register read. Use SDI to initiate another operation or set SDI to 0. To begin launching ADC conversion results on the digital interface in the following frame, set DATA_SEL = 0b. After register operations are completed, lock the register map as described in the [Register Map Lock](#) section.

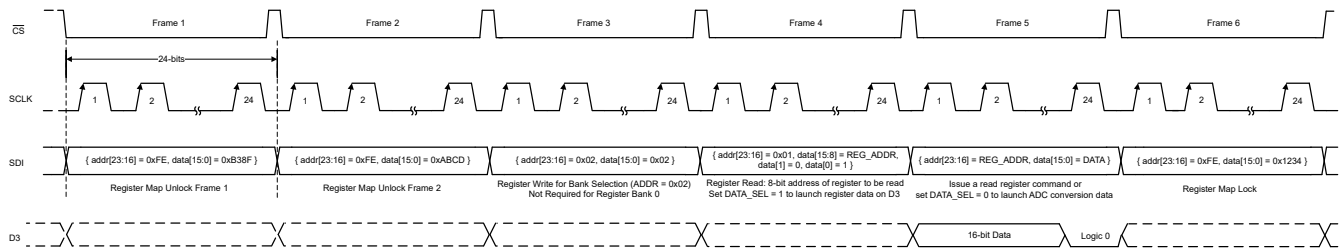


Figure 6-27. Register Read

Table 6-17. Register Read Sequence

FRAME NUMBER	REGISTER		DESCRIPTION
	ADDRESS	VALUE[15:0]	
1	0xFE	0xB38F	Unlocks the register map.
2	0xFE	0xABCD	
3	0x02	0x02	Selects register bank 1. This step is only required for register bank 1.
4	0x01	REG_READ_ADDR[15:8] = REG_ADDR, RESET[1] = 0, DATA_SEL[0] = 1	REG_READ_ADDR selects the address to be read and DATA_SEL launches the selected register data on D3 in the following frame.
5	REG_ADDR	DATA	The 16-bit data requested in the previous frame is available on D3. In this frame, issue another read register command or write DATA_SEL = 0 in address 0x01. This setting begins launching ADC conversion data on the data interface in the next frame. Repeat this step for the required number of register reads.
6	0xFE	0x1234	Locks the register map after register operations are completed.

7 Register Map

7.1 Register Bank 0

Table 7-1 lists the memory-mapped registers for the Register Bank 0 registers. All register offset addresses not listed in Table 7-1 should be considered as reserved locations and the register contents should not be modified.

Table 7-1. Register Map Bank 0

Address	Acronym	Bit 15	Bit 14	Bit 13	Bit 12	Bit 11	Bit 10	Bit 9	Bit 8
		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
0x01	Register 01h	REG_READ_ADDR[7:0]							
		RESERVED						RESET	DATA_SEL
0x02	Register 02h	RESERVED							
		RESERVED				REG_BANK_SEL[3:0]			

Complex bit access types are encoded to fit into small table cells. Table 7-2 shows the codes that are used for access types in this section.

Table 7-2. Register Bank 0 Access Type Codes

Access Type	Code	Description
Read Type		
R	R	Read
Write Type		
W	W	Write
Reset or Default Value		
-n		Value after reset or the default value

7.1.1 Register 01h (Address = 0x01) [Reset = 0x0000]

Return to the [Summary Table](#).

Figure 7-1. Register 01h

15	14	13	12	11	10	9	8
REG_READ_ADDR[7:0]							
R/W-00000000b							
7	6	5	4	3	2	1	0
RESERVED						RESET	DATA_SEL
R/W-000000b						R/W-0b	R/W-0b

Table 7-3. Register 01h Field Descriptions

Bit	Field	Type	Reset	Description
15:8	REG_READ_ADDR[7:0]	R/W	00000000b	8-bit address of the register to be read.
7:2	RESERVED	R/W	000000b	Reserved. Do not change from the default reset value.
1	RESET	R/W	0b	ADC reset control. 0b = Normal device operation. 1b = Reset ADC and all registers
0	DATA_SEL	R/W	0b	Select data to be launched on serial interface of the ADC. 0b = ADC conversion result is output. 1b = Register data is output on D3.

7.1.2 Register 02h (Address = 0x02) [Reset = 0x0000]

Return to the [Summary Table](#).

Figure 7-2. Register 02h

15	14	13	12	11	10	9	8
RESERVED							
R/W-000000000000b							
7	6	5	4	3	2	1	0
RESERVED				REG_BANK_SEL[3:0]			
R/W-000000000000b				R/W-0000b			

Table 7-4. Register 02h Field Descriptions

Bit	Field	Type	Reset	Description
15:4	RESERVED	R/W	000000000000b	Reserved. Do not change from the default reset value.
3:0	REG_BANK_SEL[3:0]	R/W	0000b	Register bank selection for read and write operations. 0000b = Select register bank 0. 0010b = Select register bank 1.

7.2 Register Bank 1

Table 7-5 lists the memory-mapped registers for the Register Bank 1 registers. All register offset addresses not listed in Table 7-5 should be considered as reserved locations and the register contents should not be modified.

Table 7-5. Register Map Bank 1

Address	Acronym	Bit 15	Bit 14	Bit 13	Bit 12	Bit 11	Bit 10	Bit 9	Bit 8	
		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	
0x08	Register 08h	RESERVED								
		RESERVED				PDN_CH[1:0]		RESERVED	PDN_CTL	
0x09	Register 09h	RESERVED					LATENCY_M ODE	RESERVED		
		RESERVED	NUM_DATA_LANES[2:0]			RESERVED	SPI_MODE[1:0]		SCLK_ECHO	
0x0A	Register 0Ah	RESERVED							SDO_PD_OV ERRIDE	
		RESERVED				DIG_DELAY_ EN	DRIVE_STRENGTH[2:0]			
0x0B	Register 0Bh	RESERVED				DIG_DELAY_D3[2:0]			DIG_DELAY_ D2[2:0]	
		DIG_DELAY_D2[2:0]		DIG_DELAY_D1[2:0]			DIG_DELAY_D0[2:0]			
0x0C	Register 0Ch	RESERVED						PD_REF[1:0]		
		RESERVED	CLK_PWR[2:0]			RESERVED				
0x0D	Register 0Dh	XOR_EN[4:0]				RESERVED	CH_AVERAG E	DATA_FORM AT		
		SAVG_MODE[3:0]			MAVG_MODE[1:0]		AVG_SYNC	SAVG_EN		
0x0F	Register 0Fh	RESERVED	TEST_PATT_2_LSB[3:0]			TEST_PATT_1_LSB[3:0]				
		TEST_PATT_ 1_LSB[3:0]	TEST_RAMP _RST	RESERVED		TEST_PATT_MODE[1:0]		TEST_PATT_ EN_CHB	TEST_PATT_ EN_CHA	
0x10	Register 10h	TEST_PATT_1_MSB[15:0]								
		TEST_PATT_1_MSB[15:0]								
0x11	Register 11h	TEST_PATT_2_MSB[15:0]								
		TEST_PATT_2_MSB[15:0]								
0x13	Register 13h	CSZ_CONVS T_INTERNAL _SHORT	RESERVED							
		CSZ_CONVS T_DELAY_DI S	RESERVED			PD_REFBUF	RESERVED			
0x14	Register 14h	RESERVED							CONVST_IN VERT	
		RESERVED					INT_BUFFER	INT_REF_MODE[1:0]		
0x17	Register 17h	RESERVED								
		RESERVED			LL_DELAY[2:0]			RESERVED		
0x39	Register 39h	RESERVED	DIS_VCMOU T	VCMOUT_SEL[2:0]			RESERVED			
		RESERVED								
0x48	Register 48h	LFN_COMP[15:0]								
		LFN_COMP[15:0]								

Complex bit access types are encoded to fit into small table cells. Table 7-6 shows the codes that are used for access types in this section.

Table 7-6. Register Bank 1 Access Type Codes

Access Type	Code	Description
Read Type		
R	R	Read
Write Type		
W	W	Write
Reset or Default Value		

**Table 7-6. Register Bank 1 Access Type Codes
(continued)**

Access Type	Code	Description
<i>-n</i>		Value after reset or the default value

7.2.1 Register 08h (Address = 0x08) [Reset = 0x0000]

Return to the [Summary Table](#).

Figure 7-3. Register 08h

15	14	13	12	11	10	9	8
RESERVED							
R/W-000000000000b							
7	6	5	4	3	2	1	0
RESERVED				PDN_CH[1:0]		RESERVED	PDN_CTL
R/W-000000000000b				R/W-00b		R/W-0b	R/W-0b

Table 7-7. Register 08h Field Descriptions

Bit	Field	Type	Reset	Description
15:4	RESERVED	R/W	000000000000b	Reserved. Do not change from the default reset value.
3:2	PDN_CH[1:0]	R/W	00b	Power-down control for the analog input channels. 00b = Normal device operation. 01b = Channel A powered down. 10b = Channel B powered down. 11b = Both channels powered down.
1	RESERVED	R/W	0b	Reserved. Do not change from the default reset value.
0	PDN_CTL	R/W	0b	Full device power-down control 0b = Normal device operation. 1b = Full device power-down control.

7.2.2 Register 09h (Address = 0x09) [Reset = 0x0000]

Return to the [Summary Table](#).

Figure 7-4. Register 09h

15	14	13	12	11	10	9	8
RESERVED					LATENCY_MODE	RESERVED	
R/W-0000b					R/W-0b	R/W-000b	
7	6	5	4	3	2	1	0
RESERVED	NUM_DATA_LANES[2:0]			RESERVED	SPI_MODE[1:0]		SCLK_ECHO
R/W-000b	R/W-000b			R/W-0b	R/W-00b		R/W-0b

Table 7-8. Register 09h Field Descriptions

Bit	Field	Type	Reset	Description
15:11	RESERVED	R/W	00000b	Reserved. Do not change from the default reset value.
10	LATENCY_MODE	R/W	0b	Control to select latency mode. 0b = Data corresponding to sample N - 1 is launched on \overline{CS} falling edge during sample N frame. 1b = Low latency mode is active. Data corresponding to sample N is launched on \overline{CS} falling edge during sample N frame. CS high until $t_{CONV} (max) + t_{LOW_LAT}$.
9:7	RESERVED	R/W	000b	Reserved. Do not change from the default reset value.
6:4	NUM_DATA_LANES[2:0]	R/W	000b	Control to select the number of lanes used for the serial data interface. 000b = ADC A data output on D[3:2] and ADC B data output on D[1:0]. 101b = ADC A data output on D3 and ADC B data output on D1. D2 and D0 are HI-Z. 110b = ADC A and ADC B data output on D3. D[2:0] are HI-Z.
3	RESERVED	R/W	0b	Reserved. Do not change from the default reset value.
2:1	SPI_MODE[1:0]	R/W	00b	Control to select the SPI mode. 00b = Mode 0. 01b = Mode 1. 10b = Mode 2. 11b = Mode 3.
0	SCLK_ECHO	R/W	0b	Control to feed-through SCLK (Pin 17) on D0 (Pin 16) . 0b = D0 outputs data as per the data interface configuration. 1b = D0 feeds-through SCLK.

7.2.3 Register 0Ah (Address = 0x0A) [Reset = 0x0000]

Return to the [Summary Table](#).

Figure 7-5. Register 0Ah

15	14	13	12	11	10	9	8
RESERVED							SDO_PD_OVERRIDE
R/W-0000000b							R/W-0b
7	6	5	4	3	2	1	0
RESERVED				DIG_DELAY_EN	DRIVE_STRENGTH[2:0]		
R/W-0000b				R/W-0b	R/W-000b		

Table 7-9. Register 0Ah Field Descriptions

Bit	Field	Type	Reset	Description
15:9	RESERVED	R/W	0000000b	Reserved. Do not change from the default reset value.
8	SDO_PD_OVERRIDE	R/W	0b	Control to override power down of serial data output lines when in 1-lane and 2-lane mode. 0b = Unused data output lines are powered down in 1-lane and 2-lane mode. 1b = All data output lines are powered up in 1-lane and 2-lane mode to support SCLK echo mode.
7:4	RESERVED	R/W	0000b	Reserved. Do not change from the default reset value.
3	DIG_DELAY_EN	R/W	0b	Control for digital delay on the output buffer path. 0b = Normal device operation. 1b = Digital delay on the output buffer path is enabled. The magnitude is controlled by DIG_DELAY_Dx fields in address 0Bh.
2:0	DRIVE_STRENGTH[2:0]	R/W	000b	Control to configure the drive strength of the digital output buffer. 000b = Normal device operation. 101b = 0.5x drive strength. 110b = 2x drive strength. 111b = 1.5x drive strength.

7.2.4 Register 0Bh (Address = 0x0B) [Reset = 0x0000]

Return to the [Summary Table](#).

Figure 7-6. Register 0Bh

15	14	13	12	11	10	9	8
RESERVED				DIG_DELAY_D3[2:0]			DIG_DELAY_D2[2:0]
R/W-0000b				R/W-000b			R/W-000b
7	6	5	4	3	2	1	0
DIG_DELAY_D2[2:0]		DIG_DELAY_D1[2:0]			DIG_DELAY_D0[2:0]		
R/W-000b		R/W-000b			R/W-000b		

Table 7-10. Register 0Bh Field Descriptions

Bit	Field	Type	Reset	Description
15:12	RESERVED	R/W	0000b	Reserved. Do not change from the default reset value.
11:9	DIG_DELAY_D3[2:0]	R/W	000b	Programmable digital delay on D3. 000b = 0ns delay. 001b = 1ns delay. 010b = 2ns delay. 011b = 3ns delay. 100b = 4ns delay. 101b = 5ns delay.
8:6	DIG_DELAY_D2[2:0]	R/W	000b	Programmable digital delay on D2. 000b = 0ns delay. 001b = 1ns delay. 010b = 2ns delay. 011b = 3ns delay. 100b = 4ns delay. 101b = 5ns delay.
5:3	DIG_DELAY_D1[2:0]	R/W	000b	Programmable digital delay on D1. 000b = 0ns delay. 001b = 1ns delay. 010b = 2ns delay. 011b = 3ns delay. 100b = 4ns delay. 101b = 5ns delay.
2:0	DIG_DELAY_D0[2:0]	R/W	000b	Programmable digital delay on D0. 000b = 0ns delay. 001b = 1ns delay. 010b = 2ns delay. 011b = 3ns delay. 100b = 4ns delay. 101b = 5ns delay.

7.2.5 Register 0Ch (Address = 0x0C) [Reset = 0x0000]

Return to the [Summary Table](#).

Figure 7-7. Register 0Ch

15	14	13	12	11	10	9	8
RESERVED						PD_REF[1:0]	
R/W-000000b						R/W-00b	
7	6	5	4	3	2	1	0
RESERVED	CLK_PWR[2:0]			RESERVED			
R/W-0b	R/W-000b			R/W-0000b			

Table 7-11. Register 0Ch Field Descriptions

Bit	Field	Type	Reset	Description
15:10	RESERVED	R/W	000000b	Reserved. Do not change from the default reset value.
9:8	PD_REF[1:0]	R/W	00b	ADC reference voltage source selection. 00b = Normal device operation. Internal reference is active. 10b = Internal reference is active. 11b = Internal reference is inactive. Force an external reference via REFIO (pin 9).
7	RESERVED	R/W	0b	Reserved. Do not change from the default reset value.
6:4	CLK_PWR[2:0]	R/W	000b	Control to select the power supply domain for the input clock. 000b = IOVDD domain. 101b = VDD_1V8 domain.
3:0	RESERVED	R/W	0000b	Reserved. Do not change from the default reset value.

7.2.6 Register 0Dh (Address = 0x0D) [Reset = 0x0000]

Return to the [Summary Table](#).

Figure 7-8. Register 0Dh

15	14	13	12	11	10	9	8
XOR_EN[4:0]				RESERVED	CH_AVERAGE	DATA_FORMAT	
R/W-0000b				R/W-0b	R/W-0b	R/W-0b	
7	6	5	4	3	2	1	0
SAVG_MODE[3:0]				MAVG_MODE[1:0]		AVG_SYNC	SAVG_EN
R/W-0000b				R/W-00b		R/W-0b	R/W-0b

Table 7-12. Register 0Dh Field Descriptions

Bit	Field	Type	Reset	Description
15:11	XOR_EN[4:0]	R/W	00000b	Control to enable XOR operation on the ADC conversion result. 00000b = XOR operation is inactive. 01111b = Bit-wise XOR operation on the ADC conversion result is active.
10	RESERVED	R/W	0b	Reserved. Do not change from the default reset value.
9	CH_AVERAGE	R/W	0b	Control to enable averaging of the two ADC channels. 0b = Normal device operation. 1b = Data output is the average of channel A and channel B.
8	DATA_FORMAT	R/W	0b	Control to select the data format for the ADC conversion result. 0b = Two's complement format. 1b = Straight binary format.
7:4	SAVG_MODE[3:0]	R/W	0000b	Control for the number of samples to be averaged in simple averaging mode. 0000b = 2 samples averaged. 0001b = 4 samples averaged. 0010b = 8 samples averaged. 0011b = 16 samples averaged. 0100b = 32 samples averaged. 0101b = 64 samples averaged. 0110b = 128 samples averaged.
3:2	MAVG_MODE[1:0]	R/W	00b	Control for the number of samples to be averaged in moving average mode. 00b = Moving average is inactive. 01b = 2 moving samples averaged. 10b = 4 moving samples averaged. 11b = 8 moving samples averaged.
1	AVG_SYNC	R/W	0b	Synchronization control for the internal averaging filter in simple averaging mode. Write 1b to trigger when averaging starts from the subsequent cycle. This should be used only during the initialization of simple averaging.
0	SAVG_EN	R/W	0b	Control to enable simple averaging. Select the number of samples to be averaged in SAVG_MODE. 0b = Simple averaging is inactive. 1b = Simple averaging is active.

7.2.7 Register 0Fh (Address = 0x0F) [Reset = 0x0000]

Return to the [Summary Table](#).

Figure 7-9. Register 0Fh

15		14		13		12		11		10		9		8	
RESERVED		TEST_PATT_2_LSB[3:0]						TEST_PATT_1_LSB[3:0]							
R/W-0b		R/W-0000b						R/W-0000b							
7		6		5		4		3		2		1		0	
TEST_PATT_1_LSB[3:0]		TEST_RAMP_RST		RESERVED				TEST_PATT_MODE[1:0]				TEST_PATT_EN_CH B		TEST_PATT_EN_CH A	
R/W-0000b		R/W-0b		R/W-00b				R/W-00b				R/W-0b		R/W-0b	

Table 7-13. Register 0Fh Field Descriptions

Bit	Field	Type	Reset	Description
15	RESERVED	R/W	0b	Reserved. Do not change from the default reset value.
14:11	TEST_PATT_2_LSB[3:0]	R/W	0000b	LSB 4-bit test pattern corresponding to ADC B.
10:7	TEST_PATT_1_LSB[3:0]	R/W	0000b	LSB 4-bit test pattern corresponding to ADC A.
6	TEST_RAMP_RST	R/W	0b	Control to reset the ramp pattern to start from 0. Toggle this register bit to reset the ramp pattern when TEST_PATT_MODE is set to ramp pattern.
5:4	RESERVED	R/W	00b	Reserved. Do not change from the default reset value.
3:2	TEST_PATT_MODE[1:0]	R/W	00b	Type of test pattern at the data interface. 00b = ADC outputs constant pattern defined in TEST_PATT_1_MSB in address 0x10 and TEST_PATT_1_LSB in address 0x0F for ADC A. Test pattern for ADC B is defined in TEST_PATT_2_MSB in address 0x11 and TEST_PATT_2_LSB in address 0x0F. 01b = Ramp pattern. 10b = Alternate pattern between AAAA and 5555 toggled at each readout.
1	TEST_PATT_EN_CHB	R/W	0b	Control to enable digital test pattern for ADC B. 0b = ADC conversion result is launched on the data interface. 1b = Digital test pattern is launched on the data interface.
0	TEST_PATT_EN_CHA	R/W	0b	Control to enable digital test pattern for ADC A. 0b = ADC conversion result is launched on the data interface. 1b = Digital test pattern is launched on the data interface.

7.2.8 Register 10h (Address = 0x10) [Reset = 0x0000]

Return to the [Summary Table](#).

Figure 7-10. Register 10h

15	14	13	12	11	10	9	8
TEST_PATT_1_MSB[15:0]							
R/W-0000000000000000b							
7	6	5	4	3	2	1	0
TEST_PATT_1_MSB[15:0]							
R/W-0000000000000000b							

Table 7-14. Register 10h Field Descriptions

Bit	Field	Type	Reset	Description
15:0	TEST_PATT_1_MSB[15:0]	R/W	0000000000000000 000b	MSB 16-bit test pattern corresponding to ADC A.

7.2.9 Register 11h (Address = 0x11) [Reset = 0x0000]

Return to the [Summary Table](#).

Figure 7-11. Register 11h

15	14	13	12	11	10	9	8
TEST_PATT_2_MSB[15:0]							
R/W-0000000000000000b							
7	6	5	4	3	2	1	0
TEST_PATT_2_MSB[15:0]							
R/W-0000000000000000b							

Table 7-15. Register 11h Field Descriptions

Bit	Field	Type	Reset	Description
15:0	TEST_PATT_2_MSB[15:0]	R/W	0000000000000000 000b	MSB 16-bit test pattern corresponding to ADC B.

7.2.10 Register 13h (Address = 0x13) [Reset = 0x0000]

Return to the [Summary Table](#).

Figure 7-12. Register 13h

15	14	13	12	11	10	9	8
CSZ_CONVST_INTERNAL_SHORT		RESERVED					
R/W-0b		R/W-0000000b					
7	6	5	4	3	2	1	0
CSZ_CONVST_DELAY_DIS		RESERVED		PD_REFBUF	RESERVED		
R/W-0b		R/W-000b		R/W-0b	R/W-000b		

Table 7-16. Register 13h Field Descriptions

Bit	Field	Type	Reset	Description
15	CSZ_CONVST_INTERNAL_SHORT	R/W	0b	Control to internally short CONVST and \overline{CS} . 0b = Normal device operation. 1b = CONVST and \overline{CS} are shorted internally. Connect CONVST/ \overline{CS} signal to CONVST pin.
14:8	RESERVED	R/W	0000000b	Reserved. Do not change from the default reset value.
7	CSZ_CONVST_DELAY_DIS	R/W	0b	Control to disable internal 5ns delay between CONVST and \overline{CS} falling edges. 0b = Normal device operation. 1b = Disable internal 5ns delay between CONVST and \overline{CS} . t_{d_CSCK} reduces to 12ns and t_{H_CVCS} increases to 5ns.
6:4	RESERVED	R/W	000b	Reserved. Do not change from the default reset value.
3	PD_REFBUF	R/W	0b	Control to power down the internal reference buffer. 0b = Internal reference buffer is active. 1b = Internal reference buffer is inactive. Use an external reference buffer and connect the external reference to the REFIO and REF_CAP pins.
2:0	RESERVED	R/W	000b	Reserved. Do not change from the default reset value.

7.2.11 Register 14h (Address = 0x14) [Reset = 0x0000]

Return to the [Summary Table](#).

Figure 7-13. Register 14h

15	14	13	12	11	10	9	8
RESERVED							CONVST_INVERT
R/W-0000000b							R/W-0b
7	6	5	4	3	2	1	0
RESERVED					INT_BUFFER	INT_REF_MODE[1:0]	
R/W-00000b					R/W-0b	R/W-00b	

Table 7-17. Register 14h Field Descriptions

Bit	Field	Type	Reset	Description
15:9	RESERVED	R/W	0000000b	Reserved. Do not change from the default reset value.
8	CONVST_INVERT	R/W	0b	Control to invert CONVST such that the sampling operation occurs on the rising edge of CONVST. 0b = Normal device operation. Sampling occurs on the falling edge of CONVST. 1b = CONVST is inverted. Sampling occurs on the rising edge of CONVST.
7:3	RESERVED	R/W	00000b	Reserved. Do not change from the default reset value.
2	INT_BUFFER	R/W	0b	Control to disable internal input buffer and reduce AVDD current. The input buffer helps improve the acquisition accuracy when the ADC is driven using weaker drive networks. It is not recommended to disable the input buffer unless the ADC driver network is sufficient to drive the input with the input buffer disabled. In ADS9316, the internal buffer is inactive by default. For signals with input frequency greater than 500kHz, the input buffer should be disabled. 0b = Internal buffer is active (ADS9317). Internal buffer is inactive (ADS9316). 1b = Internal buffer is inactive (ADS9317). Internal buffer is active (ADS9316).
1:0	INT_REF_MODE[1:0]	R/W	00b	Control to select internal reference voltage when AVDD is 5V. 00b = 4.096V internal reference. 01b = 2.5V internal reference. 11b = 3.3V internal reference.

7.2.12 Register 17h (Address = 0x17) [Reset = 0x0000]

Return to the [Summary Table](#).

Figure 7-14. Register 17h

15	14	13	12	11	10	9	8
RESERVED							
R/W-00000000000b							
7	6	5	4	3	2	1	0
RESERVED			LL_DELAY[2:0]			RESERVED	
R/W-00000000000b			R/W-000b			R/W-00b	

Table 7-18. Register 17h Field Descriptions

Bit	Field	Type	Reset	Description
15:5	RESERVED	R/W	00000000000b	Reserved. Do not change from the default reset value.
4:2	LL_DELAY[2:0]	R/W	000b	Control to select the delay after t_{CONV} when low latency data is ready for readout. 000b = Normal device operation. The delay between end of conversion and low latency data is ready for readout is 30ns. 110b = The delay between end of conversion and low latency data is ready for readout is 15ns.
1:0	RESERVED	R/W	00b	Reserved. Do not change from the default reset value.

7.2.13 Register 39h (Address = 0x39) [Reset = 0x0000]

 Return to the [Summary Table](#).

Figure 7-15. Register 39h

15	14	13	12	11	10	9	8
RESERVED	DIS_VCMOUT	VCMOUT_SEL[2:0]			RESERVED		
R/W-0b	R/W-0b	R/W-000b			R/W-00000000000b		
7	6	5	4	3	2	1	0
RESERVED							
R/W-00000000000b							

Table 7-19. Register 39h Field Descriptions

Bit	Field	Type	Reset	Description
15	RESERVED	R/W	0b	Reserved. Do not change from the default reset value.
14	DIS_VCMOUT	R/W	0b	Control to disable VCMOUT. 0b = VCMOUT is active. 1b = VCMOUT is inactive.
13:11	VCMOUT_SEL[2:0]	R/W	000b	Control to select the VCMOUT voltage. 000b = 2.23V. 001b = 2.17V. 010b = 2.11V. 011b = 2.04V. 100b = 2.49V. 101b = 2.43V. 110b = 2.36V. 111b = 2.29V.
10:0	RESERVED	R/W	00000000000b	Reserved. Do not change from the default reset value.

7.2.14 Register 48h (Address = 0x48) [Reset = 0x40E0]

Return to the [Summary Table](#).

Figure 7-16. Register 48h

15	14	13	12	11	10	9	8
LFN_COMP[15:0]							
R/W-0100000011100000b							
7	6	5	4	3	2	1	0
LFN_COMP[15:0]							
R/W-0100000011100000b							

Table 7-20. Register 48h Field Descriptions

Bit	Field	Type	Reset	Description
15:0	LFN_COMP[15:0]	R/W	0100000011100000b	Control to enable low frequency noise compensation. 0100000011100000b = Normal device operation. Low frequency noise compensation is inactive. 0100000010100001b = Low frequency noise compensation is active.

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The ADS931x with integrated averaging filters enables a low-latency, precision measurement of DC and AC signals. The following section gives an example circuit and recommendations for using the ADS931x to measure the analog $1V_{pp}$ output of sine-cosine encoders.

8.2 Typical Application

8.2.1 Analog $1V_{pp}$ Sine-Cosine Encoder Interface

The application circuit in [Figure 8-1](#) shows a 2-channel circuit to measure the output of an analog $1V_{pp}$ sine-cosine encoder. Use the [THS4552](#) as the fully differential amplifier that drives the ADS931x.

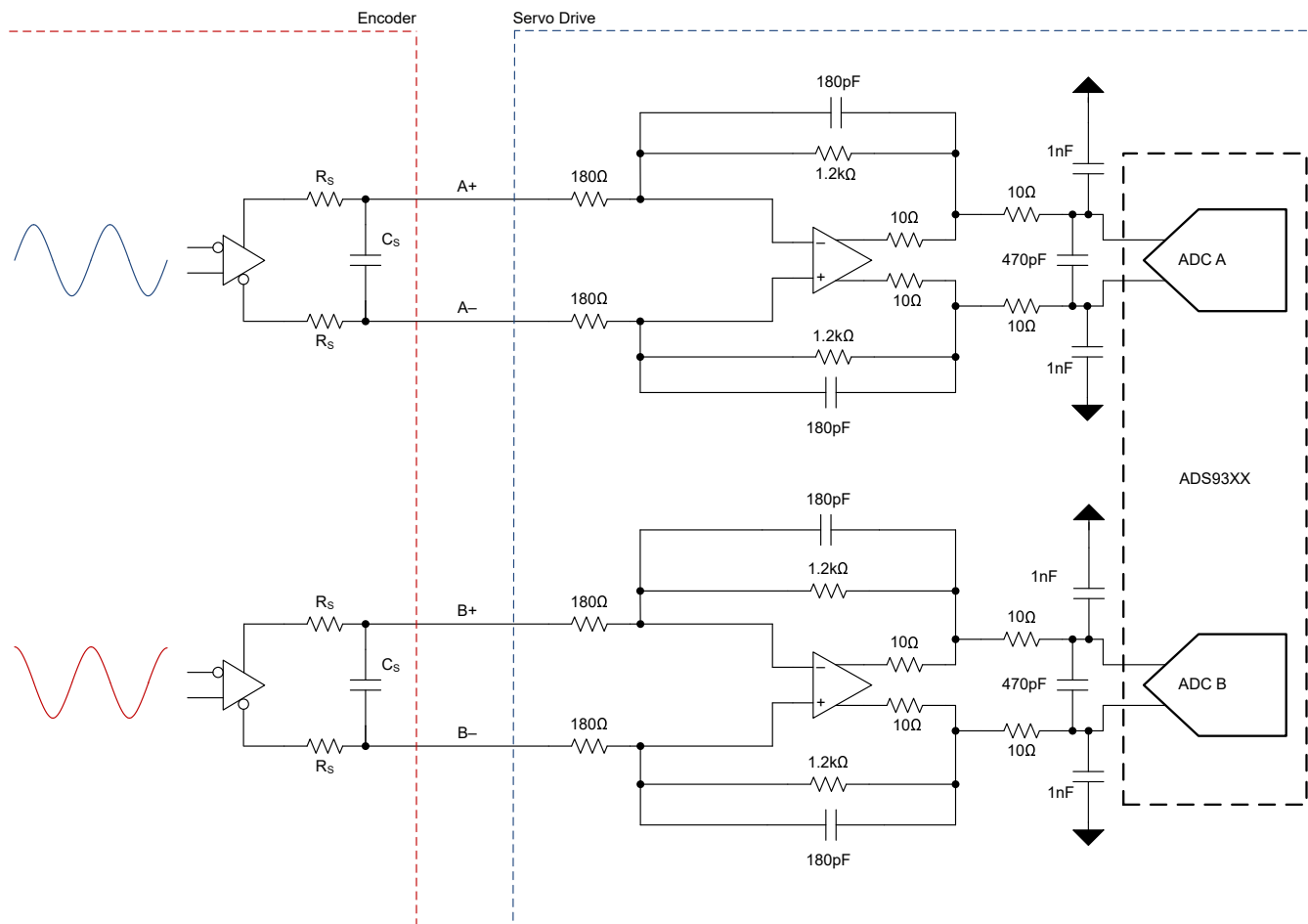


Figure 8-1. Sine-Cosine Encoder Interface Circuit With 500kHz Input Signal Bandwidth

8.2.2 Design Requirements

Table 8-1 lists the parameters for a 1V_{pp} sine-cosine encoder interface.

Table 8-1. Design Parameters

PARAMETER	VALUE
ADC resolution	18 bits
SNR	> 90dB
-3dB signal bandwidth	> 500kHz

8.2.3 Detailed Design Procedure

A typical encoder with an analog 1V_{pp} output has a maximum signal frequency of 500kHz. The -3dB cutoff frequency of the fully differential amplifier (FDA) circuit is designed for greater than 500kHz. Thus, supporting signals up to the maximum signal frequency of the encoder output. Choose the FDA such that the FDA settles the transient switching load from the sampling capacitor of the ADC within the ADC acquisition time (t_{ACQ}).

The output of a sine-cosine encoder has a typical amplitude of 1V_{pp} with a maximum amplitude of 1.2V_{pp}. The full-scale range of the ADS931x is ±V_{REF}, where the typical value of V_{REF} is 4.096V. To use the input range of the ADC, the gain of the FDA circuit is set to 6.8V/V.

To improve the SNR of the signal chain, the ADS931x offers integrated averaging filters as described in the [Programmable Data Averaging Filter](#) section. The results are shown in Table 8-2, which includes the typical SNR of the circuit with different averaging window sizes.

Table 8-2. THS4552 and ADS931x Data Summary

AVERAGING WINDOW SIZE (Simple Average)	OUTPUT DATA RATE (MSPS)	SNR (dB)	ENOB (Bits)
0	5	95.3dB	15.5
2	2.5	98.5dB	16.1
4	1.25	101.3dB	16.5
8	0.625	104.1dB	17
16	0.3125	106.9dB	17.5
32	0.15625	109.6dB	17.9
64	0.078125	112.1dB	18.3
128	0.0390625	114.6dB	18.7

8.3 Power Supply Recommendations

The ADS931x has three separate power supplies: AVDD, VDD_1V8, and IOVDD. There is no requirement for a specific power-up sequence. The data and configuration digital interfaces are powered by IOVDD. [Figure 8-2](#) shows the decoupling capacitor connections for the respective power supplies. Make sure each power-supply pin has separate decoupling capacitors.

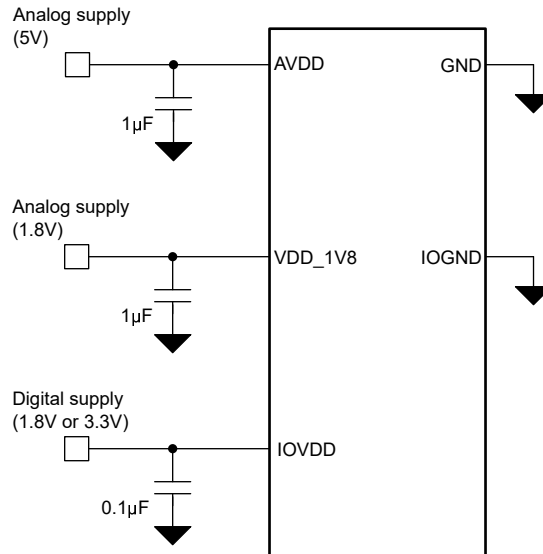


Figure 8-2. Power-Supply Decoupling

8.4 Layout

8.4.1 Layout Guidelines

[Figure 8-3](#) illustrates a board layout example for the ADS931x. Avoid crossing digital lines with the analog signal path and keep the analog input signals and the reference signals away from noise sources. Use 1µF ceramic bypass capacitors in close proximity to the analog (AVDD and VDD_1V8), and digital (IOVDD) power-supply pins. Avoid placing vias between the power-supply pins and bypass capacitors. Place the reference decoupling capacitor close to the device REF_CAP and REFM pins. Avoid placing vias between the REFIO pin and the bypass capacitors. Place the VCMOUT decoupling capacitor between VCMOUT and GND. Connect the GND and REFM pins to a ground plane using short, low-impedance paths.

8.4.2 Layout Example

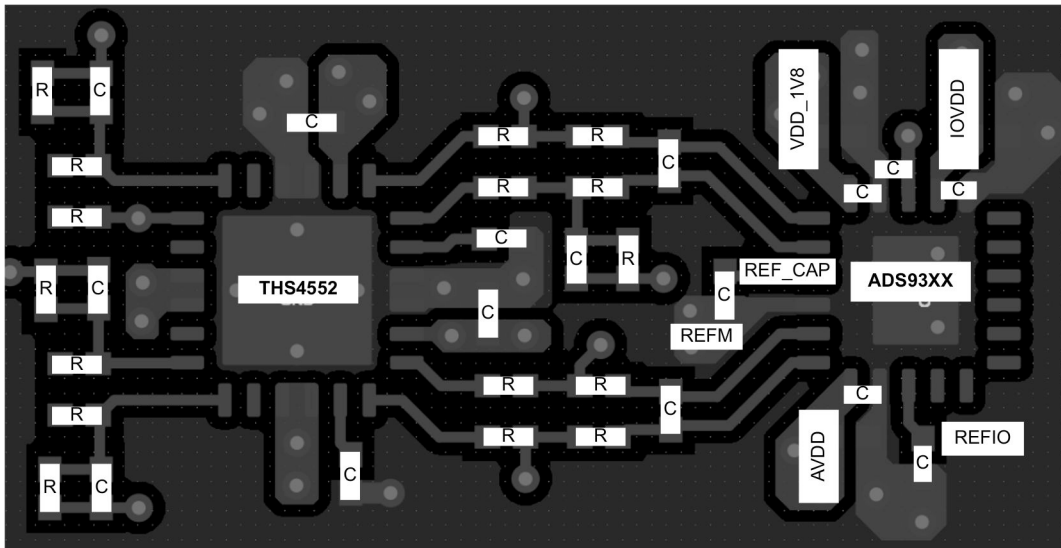


Figure 8-3. Example Layout

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISION	NOTES
June 2026	*	Initial Release

10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

10.1 Documentation Support

10.1.1 Related Documentation

For related documentation see the following:

- Texas Instruments, [REF70 2ppm/°C Maximum Drift, 0.23 ppmp-p 1/f Noise, Precision Voltage Reference data sheet](#)
- Texas Instruments, [THS4552 Dual-Channel, Low-Noise, Precision, 150MHz, Fully Differential Amplifier data sheet](#)

10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](#). Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.3 Support Resources

TI E2E™ [support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

10.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.
All trademarks are the property of their respective owners.

10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

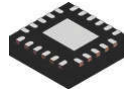
10.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

11.1 Mechanical Data

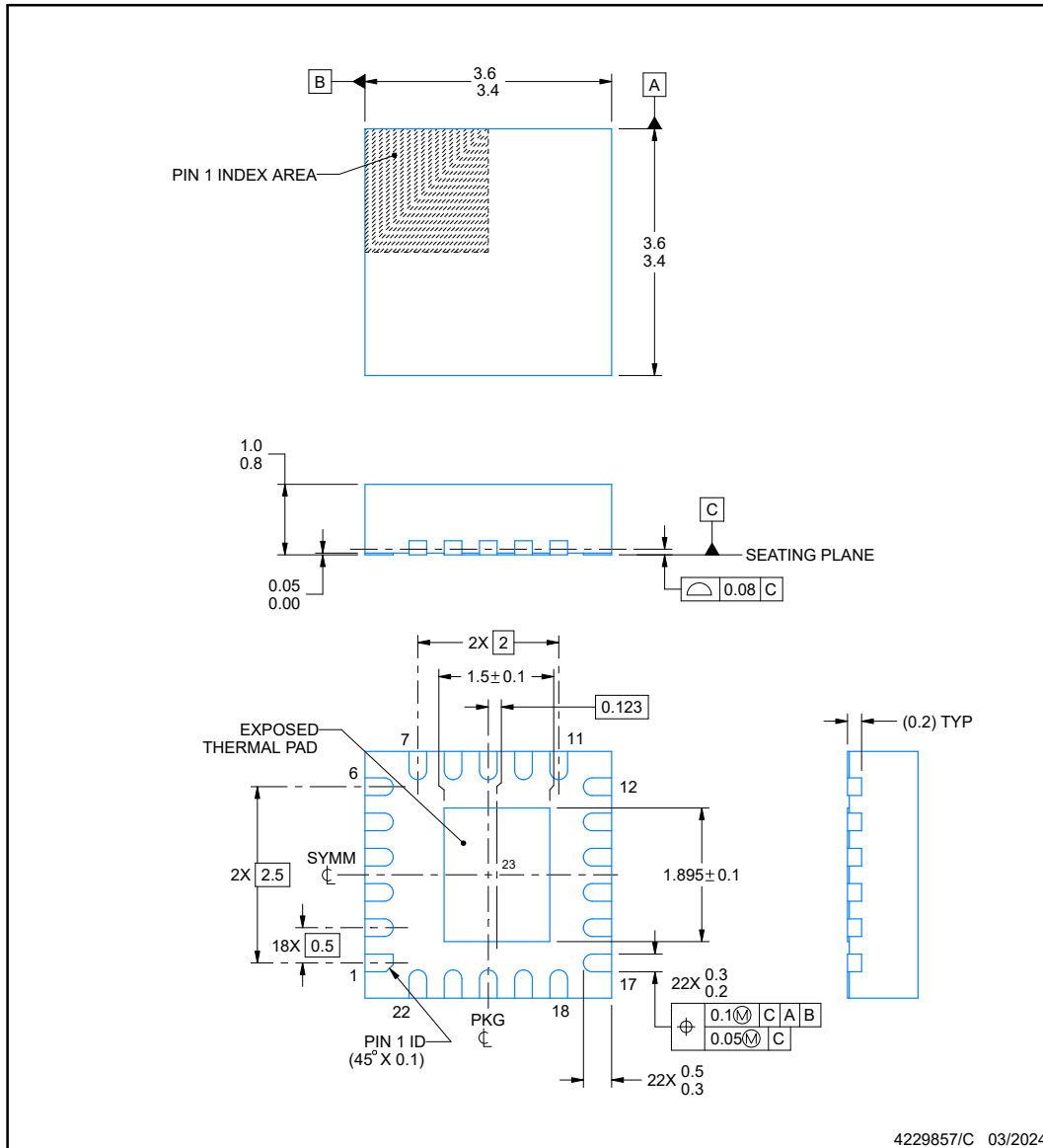


VAE0022A

PACKAGE OUTLINE

VQFN-HR - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



4229857/C 03/2024

NOTES:

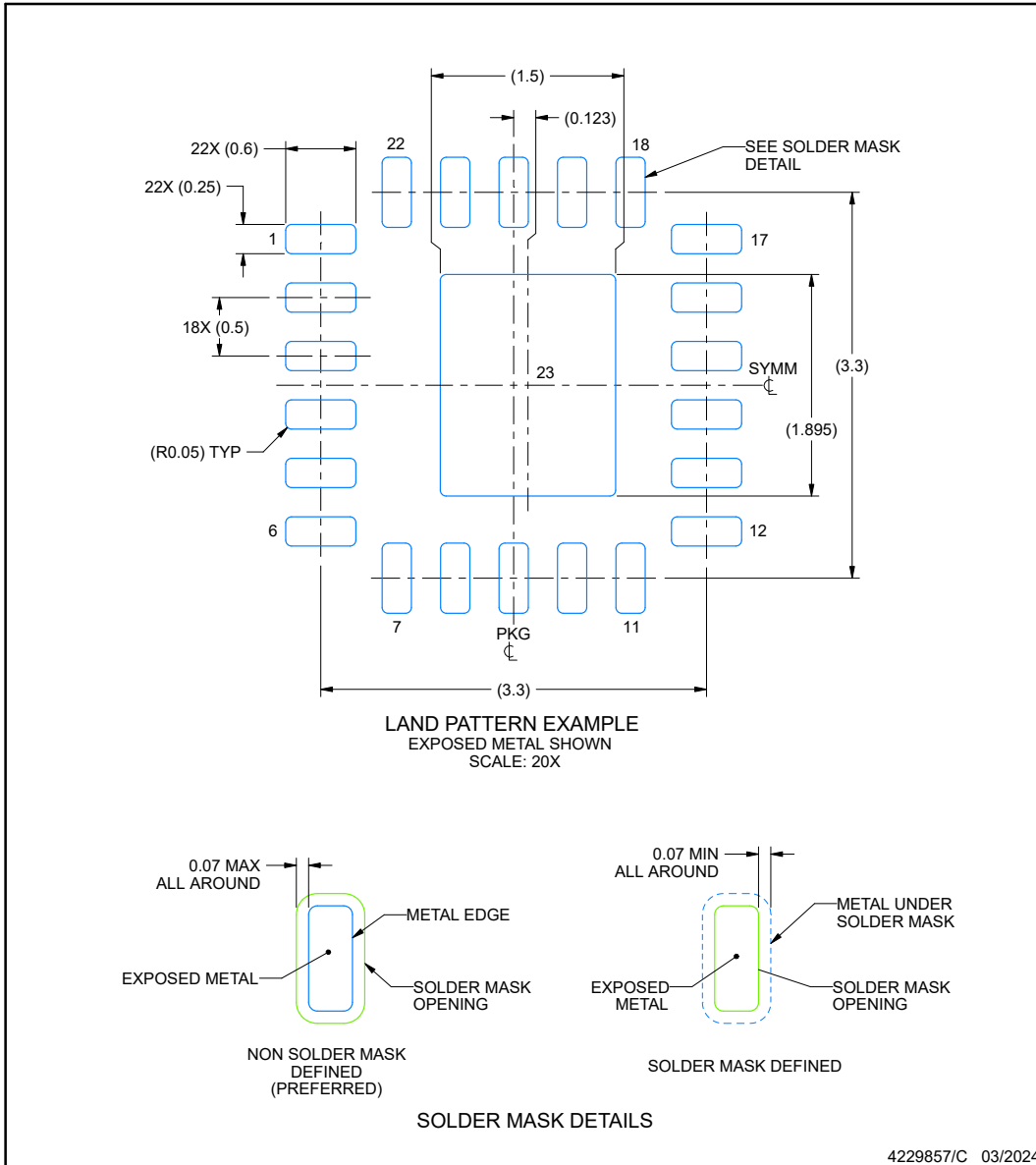
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

VAE0022A

VQFN-HR - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

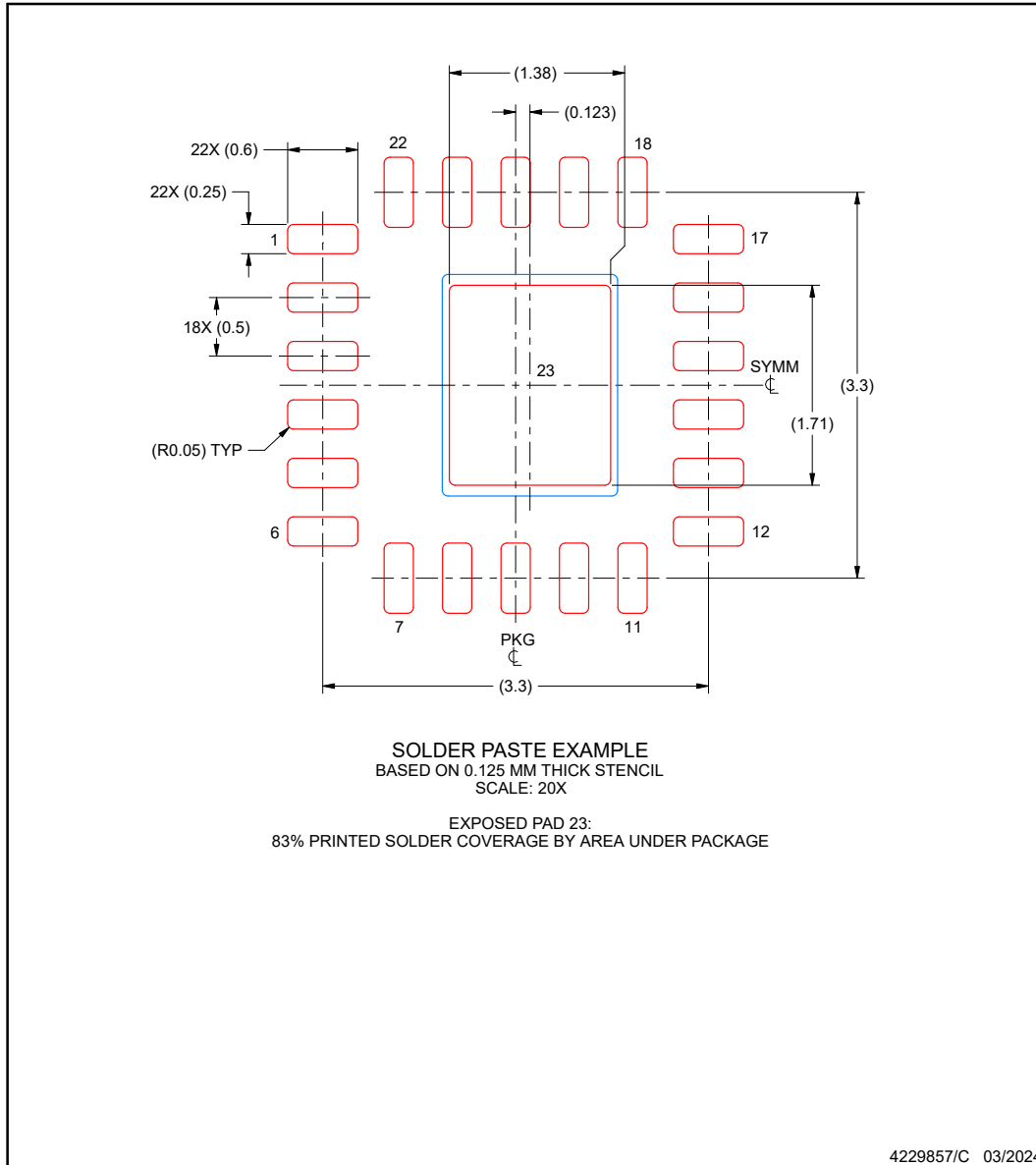
- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

VAE0022A

VQFN-HR - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#), [TI's General Quality Guidelines](#), or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2026, Texas Instruments Incorporated

Last updated 10/2025